EFFICIENT DESIGN TOWARDS HIGHLY SELECTIVE LOW/SELF-POWERED GAS SENSOR

By

MAMABOLO MASHAOLE STUART

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SUPERVISOR: PROF D.E MOTAUNG

CO-SUPERVISOR: PROF T.E MOSUANG

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Declaration

I declare that the work reported under the title "Efficient design towards highly selective low/self-powered gas sensor" submitted to the University of Limpopo for the fulfilment of a Master of Science degree in Physics is my own work that all the sources that I have used or refer to have been indicated and acknowledged by means of complete references and that this work has not been submitted before for any other degree at any other institution.

Eurer

24/01/2023

Mamabolo M.S

Date

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This work is dedicated to:

My mother

Shelly Malegola Mamabolo

My brother

Kalakala Phillimon

ABSTRACT

The daily population activities linked to the emission of various hazardous gases that can be toxic, explosive, and flammable such as CO, H₂S, SO₂, NO_x, CO₂, and volatile organic compounds have a negative impact on human lives and the environment. The development of NO₂ and CO gas sensors is vital for prompt detection due to their poisonous behaviour, which may lead to immediate deaths.

Consequently, tin dioxide (SnO₂) and vanadium pentoxide (V₂O₅) nanostructures were prepared following a facile hydrothermal method using different bases for the detection of various gases. The SnO₂-NaOH displayed hollow sphere-like structures with etched surfaces, while the SnO₂-NH₄OH and SnO₂-Urea illustrated nanoflakes and hierarchically arranged nanoflakes forming spheres, respectively. The V₂O₅ nanostructures showed nanorod like structures that varied in thickness and length with base. Structural findings exhibited improved crystalline structure of the SnO₂ in the following behaviour: SnO₂-NaOH<SnO₂-Urea<SnO₂-NH₄OH. In-situ electron paramagnetic resonance and photoluminescence studies disclosed that the SnO₂-NaOH possessed a significantly high concentration of oxygen vacancies (V₀). Consequently, the SnO₂-NaOH based sensor disclosed an exceptional selectivity to CO gas amid other target gases while operating at low temperature (75 °C). The sensor displayed a higher resistance ratio (≈32) at 60 ppm, a sensitivity of 0.49 ppm⁻ ¹, and a low theoretical detection limit of 70 ppb. Such unprecedented performance towards CO was owing to a higher number of surface defects induced by the strategy of utilizing NaOH as a base to tailor the surface properties of the SnO₂.

SnO₂/CuO-(1.0:1.0 M), SnO₂/CuO-(0.5:1.0 M) and SnO₂/CuO-(1.0:0.5 M) heterostructures-based sensors were also fabricated for detection of NO₂ gas at room temperature. The fabricated materials were characterized using various techniques, to investigate the structure, morphology, internal structure, and optical properties. The elemental mapping was also carried out to investigate the distribution of both Cu and Sn. To test their suitability in gas sensing applications, the nanomaterials were tested towards various gases at different temperatures. Among the tested sensors, the SnO₂/CuO-(1.0:1.0 M)-based sensor showed a higher response towards NO₂, in the presence of other four gases at room temperature. At 100 °C, the sensors showed a poor response, justifying that their optimal temperature is 25 °C. These results indicate that these sensors could be considered as low-power consumption sensors for the detection of NO₂.

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1.1. Overview

For decades, gas sensors such as semiconductor contact combustion, and electrochemical gas sensors have been investigated for the purpose of detecting and monitoring different gases in the environment and protecting human life [1.1]. Among these, semiconductor metal oxide (SMO) gas sensors have received extensive research and attention in the gas sensors field due to their advantages such as ease to use, production flexibility, low maintenance, low cost [1.2, 1.3], high sensitivity, rapid response and recovery time, reversibility, stability, simple electronic interface, and capacity to detect huge amounts of gases. [1.3, 1.4]. In overall SMO such as TiO₂, SnO₂, WO₃, ZnO, Fe₂O₃, etc. have been investigated, among all the SMO SnO₂ has been broadly investigated and used in the gas sensing field for the detection of various gases such as NO₂, NO, CH₄, H₂S, SO₂, CO₂, CO, etc. [1.5, 1.6], since it has great advantages over other materials in gas sensing, such as firm response, high sensibility, long-term stability, etc. Khalifa et al. [1.7]. SnO₂ nanoparticles are useful in the field of gas sensing because of their high surface-to-volume ratio, which results in improved sensitivity and adsorption capacity [1.8, 1.9].

SnO₂ gas sensors have been used to detect high humidity and inflammable gases, and the change in the electrical impendence of SnO₂ surface due to molecules adsorbed is used in measuring the electrical impendence of SnO₂ [1.10]. Toxic and combustible gases in low or high concentrations may be monitored using SnO₂ electric conductivity, which is employed as the most active layer in gas detecting devices

[1.11]. Tin oxide has a large theoretical capacity, is non-toxic, and is inexpensive, and so on, making it an excellent material for gas sensing [1.12].

The global gas sensor markets were valued at USD 1123.3 million in 2019 and is predicted to increase at an 8.66 percent compound yearly growth rate (CAGR) during the forecast period, reaching USD 1795.9 million by 2025 [1.13]. According to Grand View Research, the global market for gas sensors is predicted to reach USD 4.0 billion by 2027, with a CAGR of 8.3 percent from 2020 to 2027 [1.14]. The role of gas sensors in global economic growth is critical.

The elevated rate/level of air pollution in the environment is governed by the population activities related to the emission of toxic, flammable, explosive, and hazardous gases, which have a huge impact on the health and environment [1.15]. The outdoor sources that lead to air pollution globally include the burning of fossil fuel and biomass (generate power), transport, food production, industries, etc. which lead to the emission of various gases [1.16], whereas the indoor sources of air pollution include the use of gas and coal stoves, smoking, combustion of solid fuel, firewood, etc. [1.17, 1.18]. The emitted gases such as Methane (CH₄), Carbon monoxide (CO), carbon dioxide (CO₂), Sulphur dioxide (SO₂), Nitrogen dioxide (NO₂), nitrogen monoxide (NO), hydrogen sulfide (H₂S), Ammonia (NH₃), and volatile organic compounds. Some of these gases are invisible and when inhaled causes diseases such as respiratory diseases, lung diseases, cardiovascular diseases, etc. which causes mortality and morbidity [1.19-1.22].

Nitrogen dioxide (NO₂) is a major air polluter that is emitted from the ground by the burning of fossil fuels in manufacturing, processing, and petroleum operations such as

automobile exhaust, power plants, businesses, and households [1.23, 1.24]. NO_x is produced when oxygen and nitrogen air combine. [1.25]. NO₂ gas is most toxic and reactive, removed speedily from the atmosphere in the form of dry and wet deposition than NO [1.26]. Nitrogen dioxide is released into the atmosphere, and the population inhales around 80-90 percent of it, which is absorbed by the lungs (NO₂ forms nitrous and nitric acids when it reacts with the fluids in the respiratory fluids). According to the Department of Environmental Affairs and Tourism, those who have chronic respiratory problems are particularly vulnerable to nitrogen dioxide gas exposure. [1.27]. NO₂ is a toxic gas to human health at a concentration larger than 200 g/m³ and in the environment results in acid rain [1.28, 1.29]. NO₂ with a concentration between 15-25 ppm causes eyes and nasal irritation when exposed, also damages the cell membranes of the lungs when inhaled [1.30].

Hydrogen sulfide (H₂S) is regarded as colorless, flammable, toxic, and smelling like rotten eggs, when it reacts with air or oxygen in the atmosphere it forms an explosive mixture and reacts with iron it produces iron sulfide that will burn in air. Non-specific and anaerobic bacterial drop of sulphates and sulphur-containing organic molecules are natural sources. Natural bases include non-specific and anaerobic bacterial decline of sulphates and sulphur-containing organic compounds. [1.31, 31.2]. H₂S is a toxic substance polluter for both the environment and industrial affecting both humans, animals, and ecosystems. It is a colorless gas and heavy gas than air [1.33]. H₂S causes human nervous system damage when exposed to it, this gas is found in petroleum exploration, diverse industrial processes, and coal mines [1.34].

Ammonia (NH₃) is a toxic, irritant, corrosive, invisible, and odorless combustion applied in the manufacturing of fertilizer, refrigerant, and household cleaning products.

The emission of this gas causes atmospheric pollution, and it has effects on the eye and respiratory system and by being exposed to it results in death [1.34, 1.35].

The burning of coal, high-sulfur coal, and cars using diesel fuel results in the emission of invisible, non-flammable, and non-explosive sulfur dioxide (SO₂) gas as an environmental polluter [1.30]. SO₂ affects the respiratory system (asthma, cough, effects on children's lungs) when exposure at the high level of SO₂, also it reacts in the atmospheric level to form sulphuric acids with results in acid rain [1.36, 1.37]. The SO₂ gas reacts with moisture in the nose, throat, and nasal cavity to destroy the respiratory system nerves, also results in eye irritation, coughing, asthma, mucus secretions, coughing, and chronic bronchitis also lead to everyday hospital admission because of cardiac issues and death rates due to the highest concentration of SO₂ [1.30].

Carbon dioxide (CO₂) is an invisible, tasteless, non-flammable gas heavier than air that creates the greenhouse effect. It is created and released via the combustion of fossil fuels, human respiration, forest fires, and autotrophs plant, and it also causes oxygen deficit [1.38, 1.39]. CO₂ is a by-product of human metabolism [1.40]. The exposure limit for CO₂ is 8 hours, if inhaled at a high concentration it may result in health problems such as cancer, neurological diseases, sleep disorders, inflammation, and calcification of body tissue [1.41]. CO is invisible, odors, and tasteless with low water solubility and low reactivity, when incomplete combustion takes place, CO is emitted in the atmosphere and results in high death rates when exposed to its high level. Breathing CO results in health effects like headache, vomiting, weakness, dizziness, etc. [1.42]. Both nature and human activities contribute a lot to the formation of CO₂ levels in the atmosphere mainly by the burning of fossil fuel, extraction, and deforestation [1.43]. CO results in death by forming hypoxia with damaged cells in the

blood [1.44]. Both CO and CO₂ come from the combustion of fossil fuels and tobacco smoke mainly formed by human activities, the level of CO and CO₂ can reduce the oxygen level in the air leading to death and related diseases such as nausea, drowsiness, headaches, and unconsciousness [1.45].

Volatile organic compounds (VOC) are considered as other forms of air pollution and boils between 100-250 °C and measured at 101.3kPa, which is standard atmospheric pressure and has an impact on the formation of the tropospheric ozone layer [1.46]. VOC is classified as main sources such as traffic of road (24% of non-methane was reported in France 2002), industrial or domestic uses, such as paints, varnish or glue, and hydrocarbon evaporation [1.25]. VOC such as benzene, toluene, ethylbenzene, and xylenes (BTEX) is a threat to population health since it is categorized as a form of pollutants of the atmosphere, VOC travel a long distance from the emission spot through the air and can enter the body through the skin which will results in health effect like pathology, including asthma, atopic, dermatitis and neurologic [1.46].

Pollution Management and Environmental Health Program reported that in 2016 that the global economy has spent US\$5.7 trillion which is 4.8% of global GDP only for ambient air pollution [1.47], while the World Health Organization (WHO) probable that roughly seven million people lost their life worldwide annually due to air pollution, both humans and natural activities. WHO also indicated that about 94% of death is occurring in low-middle income countries [1.48, 1.49]. In South Africa, the death rate owing to home air pollution (indoor activities) was 34 per 100 000 in 2016, due to acute and respiratory, as well as cardiovascular illnesses [1.50]. In Africa, it was claimed in 2013 that the cost of air pollution is enormous, around USD450 billion, with people losing their lives and the need for healthcare facilities increasing as a result of the

impact of air pollution [1.51]. The WHO calculated specific limits of air pollution where people are permitted to dwell, but 90% of the world's population lives in areas that exceed the limit; in the United States, air pollution costs more than \$200 billion each year [1.52].

Recent research has shown that in low- and middle-income countries indoor air pollution is experienced from the use of solid fuels, gas stoves, tobacco smoking, heaters particularly in southern Africa [1.53], which releases various toxic and colorless gases [1.54] such as sulfur dioxide (SO₂), particulate matter (PM), oxides of nitrogen, volatile organic compounds, and carbon monoxide (CO) [1.55]. Because the majority (roughly 90%) of South Africans use kitchens, furniture, wall insulation, personal care products, cleaning products, and so on. The covid-19 regulation, which was announced nationally by the president of the RSA, required people to spend the entire day indoors, increasing the health effects caused by indoor air pollution [1.56, 1.57]. 20% of South African households experience the health effect or diseases such as cancer, low birth weight, cardiovascular disease, asthma, tuberculosis, cataracts, acute lower respiratory infections (ALRI) in children etc and 1,400 children die annually in South Africa due to indoor air pollution [1.58].

1.2. Problem statement

The rapid population growth and the daily humans' activities are linked to the emission of toxic and hazardous gases that threatens the environment and health of the population [1.59]. The necessity to create and, the evolutions of the intensified gas sensor devices for the monitoring and detection of nitrogen dioxide (NO2) and carbon monoxide (CO) gases in the environment is of great demand for protecting human

lives from harmful gases [1.60]. In South Africa, the populations are endangered from the sources that release NO₂ and CO during operation, such as car exhaust, household and mining industries [1.61, 1.62]. Gas sensors are useful in coal industries to monitor the leakage of NO₂ and CO from the containers and machines during manufacturing, which may lead to harm or explosion. Whereas in some houses where they used gas, wood, oil, kerosene, cigarettes and coal burning appliance, such as stoves, heaters, furnaces, boilers and fireplaces and gas engines, in cars and home generators, which contribute to the elevation of NO₂ levels makes gas sensor devices more preferable [1.63-1.65]. According to the World Health Organization reports in 2012, roughly three million population die yearly around the world because of the ambient air pollution. The low- and middle income countries suffer the most horrible effects. For instance, emerging countries, which have a substantial dependence on fossil fuels, such as South Africa (SA), India, etc. deal with the greater part of the health effects, production losses and mortality linked significant to air pollution. A topical study has denoted that 7.4% of all deaths in SA is related to chronic exposure to toxic gases, which cost the SA economy roughly 6% of its Gross Domestic Product (GDP) [1.66]. For instance, the accelerated rates of Tuberculosis and HIV/AIDS infection justifies that the country should consider linking the mortality rate with the air pollution. Furthermore, recent study has shown that long-term exposure to air pollution could contribute to higher numbers of COVID-19 fatalities, thus confirming a clear correlation between COVID-19 deaths with the air pollution, especially to extremely polluted countries, such as India, Italy, etc. [1.67]. Thus, the current work focuses on the production of low-powered portable gas sensors for detection of NO₂ and CO, which will provide the air quality regulator with sufficient and reliable data related to air quality.

1.3. Aim.

The aim of the study is to develop a low-powered gas sensor device that could enhance the environmental sustainability.

1.4. Objectives.

The objectives of the study are to:

- I. Synthesise inorganic p-type CuO and n-type SnO_2 and V_2O_5 nanostructures
- II. incorporate inorganic on the organic polymer matrix as an acceptor material and donor materials that can harvest solar light to produce an open-circuit voltage (Voc), which is associated to the potential at heterojunction.
- III. Attempt to synthesis both low or self-powering and selective detection methods in a singular integrated sensor device.
- IV. Synthesise noble metals as to improve the sensitivity and light scattering in the sensor and solar cell device.
- V. Investigate the long-term stability of solar cell and sensing layer when exposed to different environments.

1.4. DISSERTATION OUTLINE

Chapter One: deals with an overview and the problem statement associated with the detection of NO₂ and CO. The chapter further illustrates the thesis outline.

- Chapter Two: focuses on the literature review around the semiconductor metals oxides gas sensing. It also discusses the properties of the CuO, V₂O₅ and SnO₂.
- Chapter Three: Deals with the characterization techniques, as well as the synthesis methods used in the current work.
- > Chapter Four: Focuses on the results obtained from the preparation of individual materials, such as V_2O_5 and SnO_2 and their detection towards CO.
- Chapter Five: Focuses on the preparation of p-n SnO₂/CuO heterostructures by varying the molarity of both SnO₂ and CuO. The realization of room temperature NO₂ gas sensing derived from n-p SnO₂/CuO heterostructure is also discussed.
- > Chapter Six: Deals with the summary and future work.

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This chapter discusses semiconductor metal oxide, including their properties and applications with particular focus on gas sensing. It continues with a full review of tin dioxide from bulk properties up to the structure, before concluding with bulk properties of vanadium pentoxide and copper oxide.

2. 1. Semiconductor Metal Oxide

Semiconductor metal oxides (SMOs) with sensing properties were discovered in Japan in 1962 by Seiyama; since then, SMOs have gotten a lot of interest in research [2.1]. The first demonstration of some semiconductor was conducted in the Bell laboratories in the 1950s by two scientists Brattain and Bardeen where the modified Ge as a SMOs is dependent on the atmosphere in contact with them. Heiland later briefed that metal oxides which include ZnO alters their properties of semiconductor with respect to change in the atmosphere partial pressure of oxygen or other surrounding gases, SMO reaction with various gases and conductometric changes were introduced [2.2, 2.3]. In 1960, Seyama conducted experiments with a chemoresistive device based on ZnO thin film working at 485 °C, demonstrating the possibility of gas sensing with basic electrical circuits [2.2]. Taguchi introduced a SMOs gas sensor to the market, which consists of an alumina ceramic tube mounted with metal oxide, an electrode, and a heating coil that passes through it. He created the business Figaro Engineering Inc in 1969, which is still the biggest semiconductor producer in the world today, whereas Demarne was the first to patent and demonstrate the thin film metal oxide gas sensor based on micromachined silicon substrate in 1998 [2.8].

SMOs gas sensors are the ultimate researched of all gas sensors, and SMOs with sizes ranging from 1 - 100nm are commonly employed in gas sensors owing to their size dependant characteristics and high surface area per unit mass [2.9]. Semiconductor metal oxide has been widely active in the field of gas sensors due to its physical and chemical qualities such as low cost, high sensitivity, simplicity [2.4, 2.5], flexibility in manufacture, and ability to detect a wide range of gases. Due to qualities such as excellent selectivity and consistency with contemporary equipment, SMO-based gas sensors serve an essential role in human health and environmental safety, as well as the monitoring of numerous poisonous and hazardous gases [2.7].

Since the 1980s, research on SMO-based gas sensors has increased dramatically and drawn significant interest in the sensor field. SMOs such as Nb₂O₅, ZnO, NiO, CuO, and SnO₂ have established significant attention in the field of gas sensors. They have been utilized for gas sensors and are thought to be an effective material for detecting both reducing gases (such as hydrocarbons, alcohols, hydrogen, and carbon monoxide) and oxidising gases (oxygen and NO_x) [2.2, 2.6].



Fig. 2.1. Basic chemiresistive SMO gas sensor diagram showing side, top and bottom view.

Chemiresistive SMO gas sensor is made up of electrodes shown in fig.2.1. the resistance of the sensors and a heater on the bottom that raises the temperature sufficiently high to allow for its speed and reproducibility [2.39].

The most considered n-type semiconductors, such as SnO₂, WO₃, ZnO, In₂O₃, TiO₂, Fe₂O₃, and V₂O₅, and the p-type semiconductors, which includes CuO, NiO, Cr₂O₃, and Co₃O₄, are depicted in Fig. 2.2. In the n-type semiconductors, efforts have been focused on SnO₂, whereas in the p-type semiconductors on CuO [2.28- 2.31].



Fig. 2.2. The well most investigated n- and p-type semiconductor metal oxide gas sensors (internet search of Web of Knowledge on July 15, 2013) [2.1].

2.2. Working principle of SMO gas sensors

Semiconductor metal oxide sensors mechanism has two fundamental processes that comprise receptor and transducer as its major roles; the receptor function translates chemical data into an energy form, whilst the transducer function converts energy into signals [2.9, 2.10]. Regardless of how simple SMO measurements are in gas sensors, the detecting method remains difficult to grasp, with complications arising from several aspects that impact the functionalities of solid state gas sensors [2.3]. Wolkenstein was the first to disclose the mechanism of chemoresistive sensors based on metal oxides, where he documented the catalysis and application of electron theory of chemisorption on semiconductor [2.2]. Later, two scientists, Yamazoe and Gopel, investigated the circumstances of electric charge transmission through the SMO layer in the presence of oxygen and other reactive gases [2.3].

Based on the conductive type, semiconductor metal oxide is categorized into two types: n-type and p-type. When exposed to either reducing or oxidising gases, the indication of a drop or rise in electrical resistance is observed. The n-type resistance of the sensing layer declines when exposed to electron-donating gases (CO, H, hydrocarbons, alcohols, etc.), whereas the p-type resistances increase in the presence of electron-withdrawing gases (oxygen, NOx, etc.) [2.2, 2.6]. Formalized paraphrase. The surface redox reaction in n-type SMO gas sensors increased conductance, but the surface redox reaction in p-type SMO gas sensors decreased conductance [2.11].

Fig. 2.3 depicts the sensors connected by a neck, the grains forming large aggregates joined by grain borders, and the oxygen molecules on the surface of the grains. Adsorbed oxygen molecules absorb electrons from the conduction band on the surface of the grains and trap them as ions, resulting in a bending band and a decreased area of the electrons (space-charge layer). The sensitivity of the sensors will improve when the particle size of the sensing film is equal to or less than twice the thickness of the space-charge layer, as illustrated by Xu et al. and summarized by a semi quantitative model [2.9, 2.12]. Xu hypothesized that the neck size (X) is 0.8 times the size of the crystallite (D) and postulated that grain-boundary interactions have higher resistance when D is more than 2L. When D is smaller than 2L, the resistance grain controls the whole chain resistance and the gas sensitivity in the region [2.13].

As D becomes narrower and more comparable to 2L necks, they become more resistant and so continue to influence the sensitivity of the gas. It has been shown that on the surface of the grains, O^{-} or O^{2-} can be ionized by raising the resistance of the sensors coating by extracting electrons from the grains surface (Saxena Kanchan, 2010). This is due to absorbed oxygen species, which modify the energy band at the grain boundary. Because adsorbed oxygen species are very metastable, they oxidize the reducing gas when exposed to it, releasing the stored electron and lowering resistance [2.9]. When D>>2L for large grains, the surface interfaces with the gas phase have no effect on crystallite volume (as illustrated in Fig. 2.3. a.), the major effect of the ambient gas on sensor conductivity is seen via the grain boundary barrier for inter-crystallite charge transport from one grain to another. Fig. 2.3.c depicts the entirely depleted region as a result of the significant drop in conductivity caused by the dead conduction routes between the grains. As D<2L and the crystallites of mobile charge carriers are nearly completely depleted, the depletion region expands throughout the entire grain, resulting in a rapid fall in conductivity as the conduction channels between the grains vanish. Because there are no substantial impediments to the transmission of inter-crystallite charge, the energy bands are essentially smooth over the whole configuration of the entangled grains, and the conductivity is basically regulated by the inter-crystallite action. In this situation, it was empirically discovered that the highest gas sensitivity is reached when D<2L. However, the gas sensing mechanism of such ultrafine particles is not evident, and additional explanation is needed to explain why there is such a sharp rise in sensitivity with decreasing grain size even when D is already less than 2L [2.16-2.18].

The working temperature governs the kinds of chemisorbed oxygen species determination, as shown in the equations below. The production of oxygen species in

the surface layer of the conduction band is caused by the release of electrons, which causes the conductivity of semiconductor metal oxide to decrease when exposed to air [2.19-2.22]. Equation (2) shows that when the temperature is less than 100 °C, the oxygen ions adsorbed at the MOXs release electrons and become O₂⁻, and when the temperature is between 100 °C and 300 °C, O⁻ releases electrons from the MOX surface to become O, but when the temperature exceeds 300 °C, O²⁻ occurs on the MOX surface. The electron core–core shell structure is caused by the oxygen ions adsorbing on the surface of MOX.

$$O_2 (gas) \rightleftharpoons O_2 (ads)$$
 (1)

$$O_{2 (ads)} + e^{-} \rightleftarrows O_{2^{-} (ads)} (T < 100 \text{ }^{\circ}\text{C})$$
(2)

$$O_2^{-}(ads) + e^- \rightleftharpoons 2O^-(ads) (100 \, {}^{\circ}\text{C} - 300 \, {}^{\circ}\text{C})$$
 (3)

$$O^{-}_{(ads)} + e^{-} \rightleftharpoons O^{2^{-}_{(ads)}} (T > 300 \text{ °C})$$
(4)


Fig. 2.3. Illustration of grain size dependence of conductance in semiconductor gas sensing materials mechanisms (a) D \gg 2L, grain boundary control (b) D=2L, neck control (c) D < 2L, grain control [12]. The shaded part shows the space charge region (high resistivity), while the un-shaded part shows the core region (low resistivity) [2.15].

2.3. SMOs gas sensors characteristics.

The following values govern a device's sensing operation: response, sensitivity, reversibility, response time, recovery time, life cycle, stability, operating temperature, and dynamic range.

2.3.1. <u>Response</u>: is a ratio between the resistance in air (R_{air}) and the resistance after subjection to the gas (R_{gas}) [1]. The response is expressed by:

$$S = \frac{Rair}{Rgas}$$
(N-type semiconductor) (5)

$$S = \frac{Rgas}{Rair}$$
(P-type semiconductor) (6)

2.3.2. <u>Sensitivity</u>: is defined as the change in the sensor's output signal obtained for an incremental change in the analyte's concentration or mass, i.e., the slope of the response-vs-concentration curve. It is also defined as the sensor's ability to distinguish between the analyte of interest and potential interferences [2.23, 2.24]. The smallest concentration of the target gas volume that can be detected at the detection time is referred to as sensitivity. Sensitivity is defined as R_a / R_g for gas reduction and R_g / R_a for gas oxidation, where R_a is the resistance of the gas sensor in the reference gas [2.11].

2.3.3. <u>**Reversibility**</u>: the capacity of a sensor to recover from analyte exposure or return to its initial background / baseline condition [2.23, 2.24].

2.3.4. <u>**Response time**</u>: The reaction time of a sensor is the time it takes to respond from no load to a phase shift in load. Typically defined as the time required to climb to 90% of the final value in the measured variable from the commencement of phase input shift [2.23, 2.25].

2.3.5. <u>Recovery time</u>: of a shape-memory polymer is highly dependent upon the difference between the ambient testing temperature and the activation temperature of the polymer [2.26].

2.3.6. <u>Life cycle</u>: is the duration during which the sensor runs continuously [2.24, 2.27].

2.3.7. <u>Stability</u>: is a sensor's ability over a given amount of time to produce reproducible data [2.6]. It is a key criterion in the production of gas sensors for the real market, as the sensors should generate a reliable and reproducible signal that corresponds to 17,000 h-26,000 h of service for at least 2-3 years [2.9].

2.3.8. <u>Working temperature</u>: is the temperature equivalent to optimum sensitivity [2.24].

2.3.9. Dynamic range: is the analyte concentration level between the detection limit and the maximum limiting concentration [2.24, 2.27].

2.3.10. <u>Calibration curve</u>: defines the relation between the concentration of target gas and the signal response [2.24].

2.3.11. <u>Accuracy</u>: refers to the degree of measurement precision as compared to the true value [2.51]. Accuracy represents the degree of exactness of a measurement compared to the true value.

2.4. Challenges faced by semiconductor metal oxides.

2.4.1. Humidity.

Environmental humidity is a significant problem in the development of gas sensors and has a role in impacting the sensitivity of SMO gas sensors, determining the adsorption rate by modifying the sensitivity of SMO gas sensors. Water molecules react with oxygen on the surface, causing a drop in baseline resistance, while humidity increases, causing a decrease in sensitivity. Water molecules are adsorbed on SMO surfaces, and OH- and H+ ions generated as the outcome of the dissociative adsorption process detailed in the equation below [2.5, 2.20].

 $H_2O \leftrightarrow OH^- + H$ (7)

2.4.2. Temperature.

Arsan et al. and Yamazoe and Shimanoe [2.32] provided a concise explanation of oxygen gas adsorption and target gas detection on the surface of SMOs. Temperature has a substantial influence on the adsorption of oxygen ions and the interaction of

oxygen with analyte gases on the surface of SMO gas sensor material [2.33]. The sensitivity of SMOs is affected by the operating temperature; as the adsorption of oxygen species on the material surface increases, so does the temperature, but gas sensor sensitivity decreases. By applying high temperatures to the gas sensor, the sensors response will be affected by desorption of analyte gas, as reported by Sinha et al. [2.34] and Kamarudin et al.

Metal oxide gas sensors operate at temperatures ranging from 250 to 500 °C, when chemisorbed oxygen ions species such as O^{2-} , O^- , and O_{2-} develop on the surface. Chemical reactions restrict the response at low temperatures, whereas diffusion rates of gas molecules limit the response at high temperatures, but at the medium temperature, the rates of adsorption and desorption become identical and produce the maximum response [2.35]. Because SMOs gas sensor devices require a heater, it is advantageous to build low/self-powered sensors. SMO gas sensors can detect gas concentrations over 400°C at the material's surface because thermal energy is required to activate the oxygen ions desorbed to react adsorbed surface gas molecules and perturb the detecting reaction barriers [2.36, 2.37].

2.4.3. Selectivity.

The semiconductor metal oxide gas sensing mechanism is based on the adsorption and desorption of oxygen species on its surface, and the response (under critical conditions such as high humidity) of SMOs gas sensors on diverse gases (oxidising and reducing gases) lowers the selectivity [2.38]. Gas sensor selectivity should still be more than one. In contrast to the reaction to intervening gases, greater selectivity results in a stronger gas sensors response to a target gas. Classically, gas sensors are sensitive to several gases and exhibit cross-sensitivity. It is also difficult to attain

great gas sensor selectivity, which restricts the theoretical uses of gas sensors. Four common strategies for enhancing selectivity are (i) functionalization using noble-metal catalysts, (ii) altering the sensing temperature, (iii) employing heterojunctions and additives, and (iv) using filters. The usage of metal-organic frameworks (MOFs) as membranes has gained popularity in recent years since this new class of materials enhances selectivity [2.35]. Investigations were conducted to increase the selectivity of SMOs gas sensors toward specific gases because, as the sensors operate, the composition of the sensors would ultimately alter [2.40]. Suffers from limited selectivity, which may be remedied by simply doping the material with alternative substances.

2.5. Surface modification by noble metals.

Surface modification of SMOs is used to increase gas sensor responsiveness by utilizing noble metals such as Pt, Pd, Rh, Au, and Ag as activators of surface processes; the reactivity of a material may be altered by increasing the modifier concentration [2.41, 2.42]. Noble metals such as Pd and Pt have been employed as catalytically active dispersions on the surface of metal oxides to increase the performance and sensitivity of gas sensors [2.43]. In the case of tin oxide noble metals, Ag and Pd impact the work function while Pt works as a catalyst; the work function of Pd and Ag increases but can decrease to zero in the current reducing environment [2.44]. The additions of noble metals increase the sensitivity and selectivity of the sensor film while also lowering the operating temperature [48]. When compared to pure SnO2, Au-doped SnO2 responds strongly to CO, but when it comes to transition metals like Cu, Cu-doped SnO2 increases the reactivity of tin oxide to CO [2.45]. There are only two types of sensitization mechanisms proposed, chemical sensitization and electronic sensitization, for improving the sensing response of gas

with respect to noble metals reported in 1983 by Yamazoe et al [2.46]. Morrison also reported the understanding of the two models by noble additives, the spill-over and Fermi-level control, which have the advantage of simplicity but do not explain the sensitization complexity by metal oxide additives. The complexity is caused by the gas sensing performance, material reactivity, common surface chemistry, and the electronic result [2.47].

Furthermore, Seiyama et al. explained in 1972 that additives modifying SMOs surface under specific conditions promote sensitivity and response rate, and Yamazoe et al. discovered an inverse relationship between response and grain size in 1991 on his studies, by adding dopants on a metal for modifying the synthetic parameters control the grain size [2.22]. The promoter in chemical sensitization (spill-over) in a semiconductor surface initiates a test gas to aid its catalytic oxidation; the promoter escalates gas sensitivity as the rate of chemical process increases, whereas the concentration of negatively charged oxygen adsorbed in the surface drops; the promoter has no effect on resistance, implying the gas sensing mechanisms remain constant, as illustrated in fig 2.4.a. [2.48].

In electronic sensitization, the noble metals operate as accepters on the semiconductor oxide surface, increasing the depletion layer, the noble metal doped metal oxide resistance changing much more than the basic metal oxide, and thereby increasing the gas response [2.49].



Fig. 2.4: The illustration of (a) chemical sensitization and (b) electronic sensitization of the promoter on SnO₂ surface [2.46].

2.6. Tin Dioxide.

This section provides and overview of tin dioxide, its properties and structure.

2.6.1. Bulk properties of Tin dioxide (SnO₂).

Tin dioxide (SnO₂) is a vital semiconductor metal oxide metal owing to its distinctive properties which includes low cost, and non-toxic [2.50]. SnO₂ has been used in many applications such as gas sensors [2.51], solar cell [2.52], transparent electrodes [2.53], catalyst, surge arrestors [2.54], radioactive waste management, and optoelectronic devices [2.55],

2.6.2. Gas sensing properties of SnO₂.

Due to qualities such as low cost, high sensitivity, chemical stability, high crystallinity, and ease to use, SnO₂ semiconductor was considered one of the successful materials for gas sensing application in earlier studies/literature [2.56]. The synthesis of SnO₂ gas sensors has used a variety of methods, including autoclave hydrothermal, sol gel, and co-precipitation [2.57, 2.58], spray pyrolysis, chemical vapor deposition [59] and combustion route [2.60].

Researchers have previously faced several obstacles when attempting to improve sensor performance by focusing on gas selectivity, operating temperature (low temperature, to conserve energy), stability, responsiveness, and sensitivity of gas sensors. As a result, average reports on pure SnO₂ and doped SnO₂ material sensors have been compiled and published, regardless of the problems encountered. Khuspe et al. [2.61] observed a response of 4.5 for 100ppm concentration of NO₂ generated by sol gel technique at a temperature of 50°C. Using pure SnO₂ at room temperature, Xu et al. [2.54] found a response of 10ppm NO₂ and NH₃, as well as 1000ppm CO, ethanol, and H₂ gases using pure SnO₂ at RT where the sensors exhibited high response for NO₂ gas.

High sensitivity of SnO₂ nanoparticle is dependent of larger surface area where oxygen adsorption or desorption can take place, and by reducing the size of nanoparticle, SnO₂ sensors exhibit good performance towards various gases [2.55, 2.62].

SnO₂ is n-type semiconductor material, it is an electron carrier. The molecules of oxygen from the atmosphere (ambient air) are adsorbed on the surface of SnO₂ material forming oxygen ions, therefore the oxygen ions extract electrons from

conduction band of SnO₂ forming depletion layer and restoring the flow of electrons therefore the resistance increases. Then when reducing gas is introduced such as CH₄, CO or H₂, it donates back the electrons to the SnO₂ material occupying empty electron vacancies and eradicating the depletion layer (depletion layer become thinner), therefore the resistance of the SnO₂ material decreases as flow of charges increases. When oxidising gas such as NO₂, O₃ or CO₂ is introduced to the surface of the SnO₂ material, it extracts more electrons from the conduction band which result in the increased width of the depletion layer. The electrons flow decreases, then the resistance increases. In Fig. 2.5, illustrate the decrease in potential barriers of SnO₂ when reducing gas is introduce to its surface.

Porosity also plays a crucial role in the interaction of the reagent and the material, it allows reagent to pass in and out through it. Nanoparticle porosity adjustments have also been shown to improve sensitivity [2.63]. The porous interconnected sensor surface enhances gas sponginess, adsorption, and desorption rates, affecting the sensor's response and recovery times [2.64]. Porous non-silica metal oxide submicrospheres with large surface areas and well-developed porosity can be created to increase interfacial interactions with reactants and to facilitate reactant and product transport and diffusion [2.65].



Fig. 2.5: The schematic illustration of SnO₂ gas sensing mechanism before and after exposure to reducing gas, highlighting the change in potential barriers [2.66].

2.6.3. Electrical and optical properties of SnO₂.

Due to the presence of intrinsic imperfection, oxygen vacancies (V₀), and tin interstitials, SnO₂ semiconductor has an n-type conductivity with a wide bandgap of around 3,6 eV. The tin interstitials donor level is fully ionized in the conduction band, but the single ionized oxygen vacancies (V₀⁻) and double ionized oxygen vacancies (V₀²⁻) donor levels associated to oxygen vacancies are located (0.03 and 0.15eV below the bottom of the CB). The defects are mostly oxygen vacancies that are positioned on the surface due to the high volume to ratio in the material, which helps trap surface electrons [V₀²⁻] acts as shallow donor and (V₀⁻) acts as deep donor [2.67-2.69].

SnO₂ is a good insulator in its stoichiometric state, but nonstoichiometry, or oxygen insufficiency, enhances its conductivity. The donor features of regular native defects have been empirically validated, despite the scattered values. The production energy of oxygen vacancies and tin interstitials in SnO₂ is quite low, according to Kilic and

Zunger [2.70]. These defects can then quickly form, and defect levels can be easily ionized [2.71].

2.6.4. Magnetic properties of SnO₂.

The Co-doped TiO₂ was reported the first oxide metal discovered at room temperature to be ferromagnetic, since then additional investigation on ferromagnetism on various dilute magnetic semiconductor (DMS) such as In₂O₃, ZnO, Cu₂O and SnO₂ that exhibit ferromagnetic behaviour near, or above room temperature have been undertaken [2.72-2.74]. It has been reported that pure SnO₂ display low RT-ferromagnetism because of intrinsic defects such as oxygen vacancies (V_o) and tin interstitial (Sn_i), therefore researchers have found doping metal oxide with transition metal beneficiary to stabilize ferromagnetic [2.75]. Fig. 2.6, show the magnetic properties of Co doped SnO₂.



Fig. 2.6: M-H hysteresis curves of $Sn_{1-x}Co_xO_2$ (with $0 \le x \le 0.10$) nanoparticles [2.76].

2.6.5. Surface properties of SnO₂.

Surface and interface properties plays a crucial role for contact formation, gas adsorption, and oxygen exchange behaviour [2.77]. SnO₂ material have multiple layers, therefore its surface properties can be enhanced by removing the upper most layer especially oxygen layer [2.78]. SnO₂ surface can be improved by chemical or electronic sensitization and by addition of additives (dopants/impurities) such as Pt, Pd, Au and Ag which acts as sensitizers or catalyst [2.79, 2.80] and addition of dopants may result in the increase in SnO₂ powder surface area [2.81]. Different cation such as Ni, Mn, Fe, Mg were discovered to change the surface chemistry of SnO₂ particles at low temperature, influencing the selectivity to gases, particle behaviour in suspension and as a function of dopants concentration the grain size and crystallinity is decreased [2.82, 2.83]. The interaction of material and reagent depend also on the size and surface area of the material, the surface area of the particle increases with the decrease in size of the nanoparticle [2.80].

The surface enables the interaction of SnO₂ and gases which promotes the high concentrated charge transfer to ensure high conductivity and the creation of defects during sintering of this oxide [2.84]. Surface properties of SnO₂ are also govern by dual valency of Sn. Therefore, depending on the oxygen chemical potential of the system, the dual valency permits a reversible shift of the surface composition from stoichiometric surfaces with Sn⁴⁺ surface cations reduced to surface with Sn²⁺ surface cations [2.85, 2.86]. Sn and V₀ are the defects in SnO₂, but V₀ is considered the main defects. SnO₂ is dominated by (110), (100) and (101) facets and the (110) plane is the most studied due to its higher stability [2.87, 2.88].

2.6.6. Structural properties of SnO₂.

The tin (Sn) and oxygen (O) atoms (illustrated in Fig. 2.7) has been arranged to form tetragonal rutile structure of tin oxide (SnO₂) with a space group symmetry of P42/mnm [89]. The unit cell of tin oxide contains atoms, two Sn atoms and four O atoms, six oxygen anions located at the apex of a normal octahedron surround each tin cation, and each oxygen is surrounded by three tin atoms located at the apex of an equatorial triangle [2.90, 2.91]. The lattice parameters of stannic oxide are a = b = 4.731 Å and c = 3.189 Å [2.92]. The Sn atoms are positioned at (000) and (½, ½, ½) whereas O atoms are positioned at ± (0, 0, 0) and ± (½+u, ½-u, ½) planes of the BCC to form a distorted tetrahedron [2.93]. The dual valency of Sn is a key to understanding some features of SnO₂ surface characteristics. The dual valency enables a reversible shift of the surface composition from stoichiometric surfaces with Sn⁺⁴ surface cations to a reduced surface with Sn⁺² surface cations depending on the system's oxygen chemical potential. Surface reduction alters the surface electronic structure by creating surface states obtained from Sn 5s that are located deep within the band gap [2.94, 2.95].



Fig. 2.7. Tetragonal structure of tin Oxide, the red spheres represent oxygen atoms and purple sphere represent tin atoms.

Sensing materials	Deposition methods	Working Temperature (°C)	Analyte gas	Concentration (ppm)	Sensor response	Ref.
SnO ₂	Sol-gel	200	NO ₂	100	19	[2.61]
Fe-SnO ₂	Pechini method	25	H ₂ S	25	79	[2.96]
Ag/PANI/SnO ₂	polymerization	20	SO ₂	50	20	[2.97]
SnO ₂ @rGO	hydrothermal	25	CH4	1000	5	[2.98]
Pt-SnO ₂	precipitation	25	CH ₄	100	29	

Table 2.1: The gas sensing performance of SnO₂ gas sensors.

Table 2.1 compares the sensors response of the fabricated pure SnO₂ and doped SnO₂ by various noble metals, different techniques has been deployed in the synthesis of the sensors. The gases such as H₂S, SO₂, CH₄ and NO₂ of different concentrations as listed in table 2.1 exhibited unequal responses when exposed to the gas sensor at various operating temperature. The decorated sensors have higher response compared to the undoped sensors. Researchers reported that doping material with noble metals increases the sensitivity, response time and recovery time of the material when exposed to different gas.

2.7. Vanadium Pentoxide (V₂O₅).

 V_2O_5 is an n-type semiconductor with a band gap of 2,38eV and it has an orthorhombic structure separated by van der Waals's force between its layers, it has been reported as both single crystal's structure and amorphous V_2O_5 layer [99] which make it suitable for wide applications such as gas sensor, catalysis [2.100-2.102], infrared detectors [2.103], solar cell [2.104], and cathode for Li ion batteries [2.105]. V_2O_5 crystal has

oxygen vacancies (V₀) as its vital defects [106]. The formation of oxygen vacancies is when V₂O₅ is heated in vacuum and loses oxygen which results in dislocation and oxygen being removed from V₂O₅ [2.107], and the oxidation state of the adjacent vanadium atoms changes from V⁺⁵ to V⁺⁴ due to the presence of V₀ defects [2.108].

2.8 Copper Oxide (CuO).

Copper oxide, CuO is a transition metal oxide with a p-type behaviour and narrow band gap of 1.2eV at room temperature [2.109, 2.110]. CuO has attracted interest in research due to its unique properties in various fields such as in catalysis [2.111], gas sensors [2.112], high temperature superconductors [2.113], electrode in lithium ion batteries [2.114], varistor etc. [2.115], and characterized by low cost, excellent chemical stability and environmental friendliness [2.116-2.118], easy to manufacture and non-poisonous [2.120]. CuO materials consist of monoclinic structure and various attractive characteristics, such as super thermal conductivity, high stability, antimicrobial activity and photovoltaic properties [2.119].

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3. Characterization.

X-ray diffraction was used to analyse structural features such as crystallinity, crystallite size, and so was the samples. Scanning Electron Microscopy (SEM) and transmission electron microscopy (TEM) were utilized to investigate surface appearance, chemical composition, and interior structure. UV-visible and photoluminescence spectroscopy were used to investigate optical characteristics such as the bandgap and point defects. Electron paramagnetic spectroscopy were used to analyze the paramagnetic flaws. The Brunner-Emmet-Teller surface area analyzer was used to evaluate the porosity and surface area of the nanostructures. While x-ray photoelectron spectroscopy was used to investigate the chemical state.

3.1. X-Ray Diffraction.

X-ray diffraction (XRD) is a popular analytical method for determining crystalline structure, measuring internal stress, and the size and shape of crystalline zones. The x-ray beam strikes the material, infiltrating and scattering in various directions, resulting in scattering and incident angles shown in Fig. 3.1. The waves in motion either add up constructively or cancel each other destructively directed Braggs Law (equation 3.1.). (Equation 3.1.).Therefore each material's XRD pattern differs, indicating that each crystalline material has a distinct crystalline structure.

 $n\lambda$ =2dsin Θ

(3.1).

where n is an integer (n=1), λ = 1.5418 Å, wavelength of the beam corresponding to Cu K α emission, d is the lattice spacing between diffracting planes, Θ is the angle between incident x-rays and lattice plane [3.1].

The tetragonal lattice parameter ($a=b\neq c$) for tetragonal phase structure [3.4] is determine by equation 3.2.

$$\frac{1}{a} = \frac{h^2 + k^2}{a^2} + \frac{l^2}{c^2}$$
(3.2)

The average dimension of the crystal that create crystalline powder is related to the peak showed by Scherer equation [3.5], see equation 3.3.

$$D = \frac{\kappa\lambda}{\beta \cos\theta}$$
(3.3)

Where D is the size of the crystal, λ is the wavelength of x-ray used, β is the full width at half maximum (FWHM) of the peak in radians and K is the proportionality constant, θ is the angle.



Fig. 3.1. Illustration of Bragg's law [3.2].

3.2. Photoluminescence (PL)

PL is a technique used to identify crystalline quality and purity [3.3]. In PL beam of light traveling in the form of a photon (carrying energy, E=hf) strikes the sample resulting in the energy being transferred (energy is absorbed) to the sample in the process called photo-excitation. The absorbed photons make electrons transition from the valence band to the conduction band of the material. Then, when electrons return to the ground state releases energy which includes the non-radiative process or radiative process as shown in Fig. 3.2 (a). The energy can degenerate through light or luminescence, it is referred to as the photoluminescence process.



Fig. 3.2. (a) photoluminescence spectroscopy principles [3.6], (b) . Schematic diagram of the PL setup [3.7].

3.3. Scanning Electron Microscopy (SEM).

Scanning electron microscopy (SEM) is an imaging method with a resolution of 2nm used to image the microstructure and morphology of the material. As the low-energy electron beam is transmitted to the material and scans the sample surface, numerous

interactions in the surface occur, resulting in the emission of electrons and photons [3.8, 3.9]. An electron probe is scanning over the surface, and there is an interaction between electrons and material at different depths to produce secondary electrons and back-scattered electrons [3.10], electrons are emitted and recorded on the surface of the specimen, and image contrast is achieved by varying the height [3.9]. The texture, size, shape of the features, chemical composition, crystalline structure, and orientation of the sample built in the material are all disclosed by signals from electron-sample interactions (electron beam interacting with specimen) [3.11, 3.12]. The specimen accepts energy generated by incident electrons when it indirectly knocks out an atom, so the electrons are converted to atoms in the specimen, converted electron which discharges the atoms are called the secondary electron, and there will be electron collisions until it reaches the specimen surface [3.13].

The electron cannon emits electron beams, which go via the condense lenses to the pair of deflection coils in the electron column, where they are deflected in the X and Y axes before interacting with the sample. The deflection guarantees that the scan is rectangular [3.10], implying that the sample caught by the rectangular picture

displayed in Fig. 3.3. The interaction of the material and electron beams results in energy loss owing to scattering and absorption [3.4, 3.15].



Fig. 3.3. Basic illustration diagram of SEM [3.14].

3.4. Transmission Electron Microscopy (TEM).

Transmission electron microscopy (TEM) is a valuable technique for characterizing nanomaterials. Electron microscopy is used to explore the internal structure of a material and analyze the characteristics at an atomic scale. The TEM has a distinct advantage over the SEM in that it delivers a high spatial resolution. These approaches use transmitted electrons to magnify images, with electron-beam energies ranging from 60 to 350keV [3.16-3.18]. The electron cannon (which creates electron beams

and a condenser system to concentrate the beams into an item), the image-recording system, and the image-producing system are the three major structures of a TEM, as illustrated in Fig. 3.4. [3.19]. Because of the interaction of electrons transmitted via the specimen, the picture is expanded and concentrates on the screen (fluorescent screen) [3.20]. TEM uses an extremely high voltage to power the cathode, which subsequently allows the electron beam to generate a picture. The top of the TEM has an electron cannon, which emits electrons and drives them into the microscope vacuum tube. The TEM also employs an electromagnetic (EM) lens, by which electrons are concentrated into a very sufficient beam. The beam is then directed through the extremely tiny object, and electrons impact or scatter the screen at the bottom of the microscope, as seen in fig. 3.3. [3.21, 3.22] formalized paraphrase.



Fig. 3.4. Transmission electron microscopy diagram [3.19].
3.5. Brunauer-Emmett-Teller (Bet).

The Brunauer-Emmett-Teller (BET) theory describes the adsorption of gas molecules on solid surfaces and is used to calculate the surface area of a material. For surface area measurement, this theory applies to a system of two or more layers and employs a probing gas that does not chemically react with the adsorbents on the material's surface. Nitrogen (N₂) is often recognized as the most effective adsorbent for probing using the BET approach. As a result, the N₂ boiling temperature is commonly used in BET analysis. Surface area may be determined at many temperature scales using BET techniques, regardless of their low frequencies, using gases such as argon, carbon dioxide, and water as surface adsorbents [3.23]. The BET equation is as follow:

$$\frac{x}{V(1-x)} = \frac{1}{VmC} + \left(\frac{x.C^{-1}}{Vm.C}\right)$$
(3.4).

Where V is the volume of adsorbed molecules, V_m is the monolayer volume, C is the BET constant, and *x* is the relative pressure (P/P0) [3.25].



Fig. 3.5. Schematic illustration of BET apparatus [3.24].

3.6. X-Ray Photoelectron Spectroscopy (XPS).

X-ray photoelectron spectroscopy (XPS) is a technique for determining the elemental composition, chemical state, empirical formula, and electronic state of material [3.26-3.28]. The XPS technique includes the measurement of photoelectrons produced by the sample because of single energy x-ray photon irradiation [3.29]. The XPS spectrum is obtained by measuring the number of electrons and their kinetic energy [3.30, 3.31].

In 1887, Hertz discovered the photoelectric effect, which became the cornerstone of this approach. It is expanded in XPS that electrons are released by irradiation light on the material surface, and Rutherford came up with the equation 3.5 after the photoelectric effect in 1914, which explains the electron energy measured as the difference of x-ray energy and electron energy [3.32] as:

$$E_{k}=hv - E_{B}$$
(3.5)

In the instance of Maxwell's theory, the electron energy is directly proportional to light intensity, but this was not confirmed experimentally, it later revealed that emitted electron energy is accurately proportional to incident light frequency. Furthermore, Albert Einstein proposed that light energy is distributed discontinuously across space. The light is composed of energy quanta, which he subsequently dubbed photons, with energy HV, where h is Planck's constant, and V is light frequency. The emission occurs if the energy gained by the electron in the solid material exceeds the least amount of energy required for the electron to depart the surface (work function) [3.33]. Fig.3.6 shows the schematic diagram of an XPS setup.



Fig. 3.6. Schematic setup of XPS [3.34].

3.7. Electron Paramagnetic Resonance (EPR) Spectroscopy.

EPR spectroscopy is a prominent technique for examining unpaired electrons (the Zeeman Effect) in a material, as well as the complexity of metal or organic radicals. This technique functions similarly to nuclear magnetic resonance (NMR), explaining the incident of atomic particle resonance as the effect of high-frequency electromagnetic radiation absorption due to external magnetic fields, except that instead of spins of atomic nuclei, electron spins are excited [3.35]. In the absence of an external magnetic field, electron spins are degenerate; quantum numbers $m_s = -1/2$ (which indicates parallel directions) and $m_s = +1/2$ (which indicates antiparallel directions) characterize electron spin degeneracy by the magnetic field. Unpaired electrons can only be aligned in one of two ways (spin-up or spin-down) f the applied

field, and these alignments are proportional to the applied magnetic field intensity [3.36, 3.37]. The difference in energy after degeneracy is given by:

$$\Delta E = hf = g\mu_B B_0$$
 where μ_B is given by $\mu_B = \frac{eh}{2mc}$ and V=hf (3.6)

Where ΔE is the energy difference, μ_B is the Bohr magneton, h is Planck's constant, B₀ magnetic field, g_s is the electron spin g-factor, f is the frequency of radiation, e is the electron charge [3.38].



Fig. 3.7. Energy levels for electron spins due to applied magnetic field B [38].

3.8. Ultraviolet-Visible (UV-Vis).

The ultraviolet-visible (UV-Vis) approach is used to evaluate the transmittance and absorbance of a light that passes through a substance in the UV or visible spectrum at a specified wavelength. Not all light goes through or is absorbed by the sample in this procedure. UV-Vis has a wavelength range of 190-820 nm. The concentration of

the sample is calculated using absorbance (by using Lambert's law) in equation 3.7, and the corresponding absorbance measured over a wide range of wavelengths may be identified using the absorbance, the absorbance spectrum [3.39-3.43]. The spectrum is created chemically by the absorption of visible or ultraviolet light.

Beer-Lambert law:
$$A = \log (I_0/I) = \varepsilon lc$$
 (3.7)

where A is the absorbance, ε is molar absorption constant of the analyte for a certain wavelength, c is the concentration of the analyte (mol·l⁻¹) and l is the path length, l₀ is incident radiation, and l is the transmitted radiation. The Beer-Beer Law define the relation of Absorbance with concentration of the analyte and the path length, the absorbance is directly proportional to the analyte concentration and the path length.

UV-Vis Spectroscopy is an optical method that detects the change in UV and visible light intensity as a function of wavelength as it interacts with materials. UV-Vis spectroscopy primarily investigates electron transitions. Transitions from n orbitals to anti-bonding π^* and σ^* orbitals in conjugated organic molecules are typical instances; d-d transitions in transition metal ions; charge transfer transitions in certain organic and transition metal compounds; band gap transitions in semiconductors are further examples. Fig.3.8. the light source is directed to the dispersion device through the entrance slit, the light with different energy disperses into different frequency (colours). The light with different frequencies passes the exit slit and heat the sample to the detector where the light it measures the light absorbed, transmitted or reflected by the sample at each wavelength.



Fig. 3.8. Schematic illustration of UV/Vis spectroscopy [3.44].

3.9. Autoclave Hydrothermal Synthesis Method

In this study, the autoclave hydrothermal method was applied in the chemical synthesis of single crystals at high temperatures and pressures in a sealed and heated container under crucial solvent or mixture conditions. This synthesis process functions at temperatures above the boiling point of water and pressures more than 1 atm [3.45].

This method of synthesis has several advantages, including the ability to produce highquality crystals at high temperatures, produce nanomaterial with little or no material loss due to high vapor pressure, control nanomaterial structure through a liquid phase or multiphase chemical reactions in the synthesis procedure, low-cost apparatus, and the ability to act as a catalyst to form desired material, as well as disadvantages, such as the inability to monitor crystals. There are two types of hydrothermal synthesis reactors: polytetrafluoroethylene (PTFE) or Teflon lined autoclave reactors and PPL lined autoclave reactors (see Fig. 3.9). The hydrothermal reactor consists of two major components: a high-quality stainless-steel jacket (outer) and a Teflon liner (inner) [3.49].



Fig. 3.9. Stainless steel autoclave with the inner part Teflon liner.

3.10. The material used In the preparation of the nanoparticles.

Sodium hydroxide (NaOH), Tin chloride dehydrate (SnCl₂.2H₂O), distilled water, Urea, ammonium hydroxide (NH₄OH), vanadium pentoxide (V₂O₅), and Copper oxide (CuO).

3.10.1. Preparation of Sno₂ nanoparticle.

SnO₂ sphere were prepared using hydrothermal technique. Certain amount of Tin (ii) chloride dehydrates (SnCl₂.2H₂O) powder were dissolved in 150ml distilled water, the solution were stirred continuously at 70 °C using a magnetic rod. Ammonium hydroxide was added dropwise to maintain the pH of the solution, pH of 9.00 was obtained. The solution was then deposited in to 45ml cylindrical Teflon liner then into stainless steel autoclave reactor, heated at 180 °C for 16 hours using an ECOTHERM

oven. The contents were cooled to room temperature, the precipitates were centrifuged using mode TJ-6 centrifuge machine thoroughly with distilled water and dried at 80 °C for 24 hours to obtain SnO₂. The SnO₂ powder was annealed at 300 °C for 1 hour.

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Low Temperature Tunability on CO Selectivity, Low Detection Limit Based on SnO₂-Hollowspheres Induced by Various Bases^{*}

4.1. Introduction

The daily population activities linked to the emission of various hazardous gases that can be toxic, explosive, and flammable such as CO, H₂S, SO₂, NO_x, CH₄, CO₂ and volatile organic compounds have a negative impact on human lives and the environment [4.1-4.4]. Owed to its nature, carbon monoxide (CO) may not be openly detected by human nose unless at higher and lethal concentration. CO harming may result to instant deaths due to suffocation. This extremely poisonous gas kills numerous people yearly because of building and shack fires and the use of gas heaters in homes [4.5]. Therefore, fabrication of portable CO gas sensors is very vital for prompt detection of this deadly gas. Various semiconductor metal oxides (SMOs) (e.g., SnO₂, CuO, TiO₂, V₂O₅ and WO₃) have been used as gas sensors for detection of CO [4.6-4.9]. Amongst these SMOs, SnO₂ remained the most used material in the gas sensing field, due to its unique properties, such as bandgap of 3.6 eV, superior stability, accessibility, low-cost and can be easily synthesized in various forms. Additionally, it possesses superior electron mobility (160 cm²·V/s) [4.10-4.12].

Nonetheless, SnO₂ has been suffering poor sensitivity as well as selectivity when exposed to a target gas. In addition it also operates well at higher sensing temperature, which result to higher power consumption. Several studies have attempted to improve

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the gas sensing performance of SnO₂ through altering its properties, by either doping, or incorporating other metal oxides to form heterostructure. For instance, Mauraya et al [4.13] has reported the CO sensing characteristics of SnO₂ prepared using vacuum evaporation. They reported a response of 70.7% towards 915 ppm CO gas at a functional temperature of 400 °C. Kim et al. [4.14] prepared Au-SnO₂-co-decorated WS₂ nanosheet based sensor and tested towards CO gas. They reported a response of roughly 3.7 towards 50 ppm CO with a tuned applied voltage of 4.7 V. Viet et al. [4.15] reported a CO response of roughly 1.5 at 150 °C. The CuO-SnO₂ nanocomposites-based sensor prepared using co-precipitation method showed a response of 3.52% towards 100 ppm CO gas at 200 °C. Kim et al. [4.16] reported a low operating temperature gas sensing for the detection of CO gas utilizing the 2D MoS₂ gas sensor.

In contrast to SnO₂, vanadium pentoxide (V₂O₅), is a unique n-type material composed of a layered structure, having properties, such as good chemical and thermal stability, wide optical band gap, good thermoelectric property, which makes it applicable in gas sensing applications. Though, it is vital to point out that limited work has been done on CO gas sensing using a V₂O₅ based sensor. For instance, Yeh et al. [4.17] prepared CuO/V₂O₅ hybrid nanowires using a facile chemical route. They reported a response of 1.5 towards 50 ppm CO at 300 °C. Moreover, Abkenar et al. [4.18] reported on CO sensing using Au-V₂O₅ nanosensor, which showed a response of 58 400 °C. Based on the points mentioned above, it is clear that limited studies exist on the low operating temperature sensing, using bare SnO₂ and V₂O₅ nanostructures.

Thus, in the current work, we report on the low temperature tunability on the CO selectivity derived from pure SnO₂-Hollowspheres prepared using a NaOH base. The results showed the effect of base in achieving different morphologies and surface

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defects which later contribute to the sensing performance. The presence of O_v was confirmed using both in-situ photoluminescence (PL) analyses and electron paramagnetic resonance (EPR).

4.2. Experimental method

4.2.1. Materials

Tin chloride dehydrate (SnCl₂.2H₂O) and vanadium pentoxide (V₂O₅), sodium hydroxide (NaOH, purity 99%), ammonium (NH₄OH) (30-33% NH₃ in water, 99.99%), and Urea (purity 99%), were purchased from Sigma-Aldrich and were used without further purification.

4.2.2. Synthesis of nanoparticles.

The influence of base on the morphology of pure SnO₂ and V₂O₅ nanostructures was investigated using NaOH, NH₄OH and Urea at the reaction temperature of 180 °C. As a result, the certain amount of SnCl₂.2H₂O, and V₂O₅ powder were added in separate beakers with 150 ml of distilled water, the solutions were stirred for one hour using magnetic stirring at 70 °C. To maintain the pH, NaOH, NH₄OH and Urea were added drop wise until the pH of 9.00 of each solution was recorded/reached using a pH meter. The solutions were then transferred into a Teflon lined stainless steel autoclave (purchased from Labotec (pty) LTD) and were heated for 16 hours in an oven at 180 °C. The products were washed and centrifuged discarding the solvent ten times using a time interval of ten minutes in a mode-TJ-6 centrifuge machine. The final powders were dried at 80 °C for 24 hours in the oven, before annealed at 450 °C and grinded using mortar and pistil. Then SnO₂, and V₂O₅ powders were produced and recorded

as SnO₂-NaOH, SnO₂-NH₄OH and SnO₂-Urea, and V₂O₅-NaOH, V₂O₅-NH₄OH and V₂O₅-Urea.

4.2.3. Characterization techniques

The structure of the materials was probed using a PANalytical X'-pert PRO-PW 3040/60 X-ray diffractometer (XRD) furnished with a source radiation of CuK α (λ = 0.154 nm). The scanning electron microscopy (SEM, ZEISS Auriga)) equipped with an energy dispersive X-ray spectroscopy (EDS) facility was utilized to examine the surface morphology and elemental composition of the materials. The surface defects and paramagnetic features were probed using a completely powered imaging spectrometer with a Kimmon IK series 325 nm laser photoluminescence spectroscopy and FSA JEOL electron paramagnetic resonance (EPR), respectively.

4.2.4. Gas Sensing Characteristics

Various SnO₂ and V₂O₅ sensing devices were developed by pasting the unvaryingly slurry onto the alumina substrates (size: 2 mm × 0.5 mm) with two Pt electrodes. The fabricated films were dried at 200 °C in an oven for an hour to maintain a proper adhesion. A commercial KSGAS6S KENOSISTEC gas testing station (acquired from Italy) was utilized to study the change in the sensor resistance. The atmospheric conditions were controlled using MKS Instruments Deutschland GmbH mass flow controllers, which provided 5 - 100 ppm concentrations of carbon monoxide (CO), methanol, ethanol, hydrogen sulphide (H₂S), methane (CH₄) and nitrogen dioxide (NO₂) into a sealed testing chamber containing a volume of 1 litre by diluting the analyte gases in synthetic air. The output signal was extracted by applying a constant bias of 0.5 V to the sensing materials. The analyses were accomplished at different

operational temperatures of 25, 75 and 150 °C. The change in sensor resistance was monitored by a Keithley 6487 picoammeter/voltage source meter. Relative humidity (RH) measurements were regulated at 40 % using a water bath humidity generation chamber. The sensor response was computed by the change of the resistance utilizing the following formulas: R_a/R_g and R_g/R_a (R_a : resistance in dry air, R_g : resistance in gas) for reducing and oxidizing gases, respectively.

4.3. Results and discussions

4.3.1. Surface morphology and Structural Characteristics

The effect of various bases, such as NaOH, NH₄OH and Urea on the preparation of pure material SnO₂ is discussed in this section. Fig. 4.1 (a) and (b) show low magnification and high magnification images of SnO₂-NaOH. A porous cluster with a chirped/etched like surface is shown in Fig. 4.1 (a). More additionally, high magnification images in Fig. 4.1 (b) revealed hollow-spheres distributed on the surface. Fig. 4.1 (c) and (d) shows the low magnification and high magnification images of the SnO₂-NH₄OH. The low magnification displays block like structures, which appear to be covered and surrounded by nanoparticles on the surface. The high magnification images of SnO₂-Urea exhibit spheres in Fig. 4.1(e) while the high magnification indeed shows hierarchically arranged nanoflakes forming a spherical shape which has a diameter range of $0.3-1\mu$ m. The study indicates that different bases have the effect in the structural morphology of the material. The EDS mapping showed that the materials consisted of Sn and O only (see supporting information, Fig. S1). The carbon peak was due to the carbon tape used during the sample preparation.



Fig. 4.1: SEM images of low and high magnification of (a-b) SnO₂-NaOH, (c-d) SnO₂-N4OH and (e-f) SnO₂-Urea.

The influence of different bases on the morphology of the V₂O₅ nanostructure was also investigated as shown in Fig. 4.2. The low- and high- magnification images in Fig. 4.2 (a) and (b) show V₂O₅ –NaOH nanorods like structure, which are attached to one another and well aligned. The rods have a diameter range of 100 – 150 nm and length

that is more than 5 μ m. The low and high magnification of V₂O₅-NH₄OH in Fig. 4.2 (c) and (d) displayed shorter rods, which appeared to have been broken. Upon using the Urea as a base (see Fig. 4.2 (e) and (f)), the low magnification indeed confirms that thicker rod (diameter range ~10 μ m) like structure are favoured, which are hexagonal in shape. The length of this hexagonally shaped V₂O₅-Urea is also in the range of > 30 μ m.



Fig. 4.2: SEM images of low and high magnification of (a-b) V_2O_5 -NaOH, (c-d) V_2O_5 -NH₄OH and (e-f) V_2O_5 -Urea.

Fig. 4.3 illustrates the XRD patterns of the various SnO₂ and V₂O₅ prepared using three different bases, which included NaOH, Urea and NH4OH. The diffraction patterns in Fig. 3 (a) show peaks at $2\theta = 20^{\circ}$, 34° , 38° , 52° , 54° and 63° corresponding to (110), (101), (200), (211), (220) and (310), respectively. An additional peak positioned at 30°, is observed on all the samples and indicating poor crystallization of Sn₆O₄(OH)₄ as hydroxide intermediate are still present post annealing (confirmed by ICDD 46-1486) [4.19]. As noted, the SnO₂-NH₄OH nanostructure presents improved crystallinity in comparison to SnO₂-NaOH, and SnO₂-Urea as indicated by sharper peaks. Furthermore, a shift to higher angles due to increased strain was also observed in this order: SnO₂-NaOH> SnO₂-Urea > SnO₂-NH₄OH, as observed in magnified patterns of (101) peaks (see Fig. 4.3(b)). This is further justified by the calculated crystallite sizes of 8.6 nm, 8.8 nm and 16.9 nm for the SnO₂-NaOH, SnO₂-Urea, SnO₂-NH₄OH, respectively. The crystallite sizes were calculated using the Scherrer formula. Fig. 3 (c) displays the XRD patterns of the V_2O_5 nanostructures prepared using various bases. As presented, the sample prepared using NaOH base indeed shows an orthorhombic V₂O₅ structure (confirmed by the ICDD 41-1426), showing peaks at 20.2. 26.1, 30.91, 41.1, and 51.1° correspond to (001), 110, (301), (002) and (020) respectively. Nonetheless, the samples prepared using NH₄OH and Urea display several phases, which may include the V₂O₃ and V₄O₇. Moreover, we carried out the EDS, which indeed showed the materials do not contain any impurities.



Fig. 4.3: XRD patterns of (a) SnO₂- NaOH, SnO₂-NH₄OH, SnO₂-Urea and (b) V₂O₅-NaOH, V₂O₅-Urea and V₂O₅-NH₄OH.

4.3.2. Electrical and Gas Sensing Characteristics.

The electrical characteristics of SnO_2 and V_2O_5 based sensors were examined toward both reducing and oxidizing gases at various operating temperatures. Fig. 4 (a) and (b) illustrates the variation of the resistance in air (R_a) as a function of operational temperature. As noted from the Fig., the R_a decreases with the increase operational temperature, displaying the distinctive intrinsic behaviour of a semiconductor metal oxide-based sensors. All the sensors follow the same trends of R_a changes with operational temperature. Both SnO₂ and V₂O₅ based sensors prepared from NH₄OH base displayed higher R_a compared to other bases. This increased electrical resistance could be associated with improved crystallinity [4.20].

To understand the role of operational temperature on the gas sensing performance of various sensors towards different gases, the sensors were tested at 25, 75 and

150 °C, as shown in Fig. 4.4. According to Safety, Health and Welfare at Work (Chemical Agents) Regulations, 2001, the maximum occupational exposure limit value (OELV) concentration of a CO at work for 8 hours is 20 ppm [4.21], while for Occupational Safety and Health Administration Permissible Exposure Limits (OSHA PEL) for CO is 50-60 ppm for 8hr shift [4.22]. Furthermore, the American Conference of Governmental Industrial Hygienists (ACGIH) has recommended a CO a threshold limit value (TLV) of 25 ppm [4.22]. Consequently, in the current work we showed the response versus temperature towards 20 and 60 ppm CO. Remarkably, while the sensors were able to detect either 20 or 60 ppm CO at room temperature, nonetheless, the sensors showed a good response at low operating of 75 °C. At higher temperature of 150 °C, the sensor response reduced, signifying that the 75 °C is the optimum temperature. Such low operating temperature demonstrates that the sensors indeed reveal a characteristics of low power consumption. Among the sensors, the SnO₂-NaOH based sensor revealed a superior response of roughly 16 at 20 ppm, more interestingly the response doubled (i.e., $R_a/R_g \approx 32$) as the concentration increased to

60 ppm. Kim et al. [4.14] reported a response of 3.687 within the CO concentration of interest~ 50 ppm, however, this was achieved under an optimized applied voltage of 4.7 V using the Au-SnO₂-co-decorated WS₂ nanosheet gas sensor. A higher CO response of roughly 52% was observed by Mauraya et al. [4.23] at an operating temperature of 400 °C using PdO/SnO₂ structure prepared by a direct oxidation of Pd metal on SnO₂ films. According to the authors, such multi-fold improvement of CO response was related to (i) improved surface area induced by PdO loading that delivered additional free surface sites for the adsorption of oxygen, (ii) increase of oxygen molecules catalytic dissociation and (iii) modulation of the electron depletion region at PdO/SnO₂ p-n heterostructure because of ionic oxygen adsorption/desorption. Furthermore, Zhou et al. [4.26] reported a CO response of 23.18 at an enhanced temperature of 250 °C at 100 ppm. They associated such improved CO response to rapid rate of diffusion, easy adsorption of polar CO molecules, and lower activation energy of CO to CO₂ conversion in comparison to other gaseous molecules [4.27].

To display the real reason behind the higher response observed at 75 °C, the realtime response ability of SnO₂-NaOH based sensor to various CO concentrations, the response/recovery properties of the sensor towards 5- 100 ppm CO at 75 and 150 °C were investigated, as depicted in Fig. 4.4 (e) and (f). As noted, the sensors displayed a noticeable electrical signal changes at various CO concentrations. The sensors presented a response when the gas was injected in the chamber and recovered almost completely when the gas was removed. The rapid decrease in resistances upon exposure to CO gas in all operating temperatures confirmed that the sensors have the n-type semiconducting properties.

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Fig. 4.4. (a-b) Resistance in air (R_a) versus operating temperature, (c and d) response versus operating temperature and (e and f) real-time resistance at 75 and 150 °C.

Fig. 4.5 shows the response versus gas CO concentration for various gas sensors at operating temperature of 75 °C. The sensing response of the SnO₂ derived from NaOH base showed improved response in comparison to other sensors at 75 °C thereafter at higher temperature the response reduced (see Fig. A2). Such decrease is described as the adsorption saturation, when the operational temperature increased the target gas was desorbed before interaction with oxygen ions on the SnO₂ surface, consequently reducing the response [4.26].

As demonstrated in Fig. 4.5 (a), a linear increase in response is observed from 5-60 ppm CO exposure to SnO₂-NaOH, SnO₂-Urea and SnO₂-NH₄OH. As previously noted, a concentration of 20-50 ppm is recommended as a OELV or TVL for 8hr work-shift. This denotes that the current sensor could be very useful for detection of CO at workplace or households. As presented in Fig. 5 (c), the sensors responses were fitted with a linear fit, demonstrating a pronounced potential in practical applications. SnO₂-NaOH demonstrated higher sensitivity of 0.30 ppm⁻¹ in comparison to other sensors, SnO₂-NH₄OH (i.e., 0.21 ppm⁻¹), SnO₂-Urea (0.05 ppm⁻¹), V₂O₅-NaOH (0.0008 ppm⁻¹), V_2O_5 -NH₄OH (0.0033 ppm⁻¹) and V_2O_5 - Urea (0.005 ppm⁻¹). The correlation coefficients R² of approximately 0.97-1, validated that the sensors are consistent and can be considered as promising for quantitative detection of CO gas. Besides, based on the standard that is defined by IUPAC (signal-to-noise ratio of 3), the theoretical limit of detection of various sensors towards CO gas was calculated as depicted in Fig. 4.5 (c). As noted, the SnO₂-NaOH based sensor displayed the lowest Limit of Detection (LoD) compared to its counter, thus this further confirm the significant role of oxygen vacancy in enhancing the sensing abilities. This minimal LoD is lesser than 5 ppm that could not be practically tested because of the sensor measurement system limits. This smaller LoD could be used to detect CO gas at the lowest ppb

concentration. This establishes that the current sensors offer an effective key for the CO detection at ppb-level for indoor air quality monitoring.



Fig. 4.5: Response versus CO concentration for various sensors tested at 75 °C, (b) sensitivity plot of various SnO₂ based sensors and (c) LoD of various sensors towards CO at 75 °C.

To further meet the requirements for real life sensor application, rapid response (T_{res}) and recovery (T_{rec}) times are vital parameters in real application. Generally, the T_{res} and T_{rec} are times required for the resistance of the sensor to fluctuate from R_a to 90% of the total resistance change (R_g) in the instance of adsorption and desorption, respectively. Fig. A3 displays the T_{res} and T_{rec} of all the sensors towards 60 ppm CO gas. As demonstrated, the SnO₂-NaOH displayed a remarkable T_{res} and T_{rec} in comparison to its counterparts at 75 °C. Such low response and recovery percentage maybe because of the increased oxygen vacancies (Vo), resulting to increase conductivity of the sensor, further confirming a rapid charge transfer swiftness during the sensing process. Generally, in SMO-based gas sensor, an absolute response-recovery sequence comprises the adsorption-desorption of the CO gas on the surface of sensing layer and the charge-transfer process.

Selectivity is also vital parameter in gas sensing, more especially for real application. Thus, Fig. 4.6 demonstrates the selectivity radar plot of six sensors tested towards CO in the presence of other interference target gases, including ethanol, methanol, CH₄, H₂S and NO₂ at optimized temperature of 75 °C. As presented in Fig. 4.6, the sensors displayed a superior selectivity towards CO gas. The detection of the sensors towards the target gases, are as follows CO>H₂S>ethanol>methanol>NO₂>CH₄. Compared with the other sensors, the SnO₂-NaOH displayed superior selectivity towards 60 ppm CO at 75 °C. Such selectivity could be justified by lower bonding energy of CO (358 kJ/mol) associated to its equivalents, such as CH₄ (431 kJ/mol), H₂S (432 kJ/mol), NO₂ (473 kJ/mol), ethanol (458 kJ/mol) and methanol (427 kJ/mol) [4.27, 4.28]. Because of the comparatively less bond energy of CO, the elevated reaction activity of CO molecules contributed to the enhanced selectivity, mainly at the low operative temperature [4.29]. The CO detection can also be justified by rapid rate of diffusion, easy adsorption of polar CO molecules, and lesser activation energy of CO to CO₂ conversion in comparison to other gases [4.30]. Previous studies on pristine SnO₂ based sensor have displayed very inferior CO selectivity [4.31, 4.32]. Thus, the current selectivity clearly shows that our sensor could be used for detection of CO at low temperature.

Moreover, the cross-selectivity of the various sensors towards CO and the other interfering gases, H₂S (S_{CO}/S_{H2S}), ethanol ($S_{CO}/S_{Ethanol}$), NO₂ (S_{CO}/S_{NO_2}), methanol ($S_{CO}/methanol$), and CH₄ (S_{CO}/S_{CH_4}) was examined in Fig. 4.6 (b). This relatively higher response ratio of (S_{CO}/S_{NO_2}) suggests that the NO₂ did not interfere much with the CO gas, in comparison to H₂S which showed very low response ratio indicating higher interference of H₂S.

Response versus CO concentration, Fig 4.6 (d) – (e) repeatability at 20 and 40 ppm CO in the presence of 40 %RH. Real-time resistance plot of showing a long-term stability of a fresh sensor and that tested after three months and Fig 4.6 (f) – (g) response versus CO concentration of a fresh sensor and that tested after three months. In addition to the selectivity, the long-term stability is also another vital parameter for real application. As a result, we have studied the long-term stability of the SnO₂-NaOH based sensor. Fig. 4.6 (b) displays the real-time resistance plot of the fresh sensors and that tested after three months in dry air. The real-time resistance plot still shows a clear response after three months, though it drifts compared to the fresh sensors. The response plot clearly shows that after three months the sensors were stable at lower concentrations (5-10 ppm), only drifted by at 18, 22 and 40 % at 20, 40 and 60 ppm, respectively.



Fig. 4.6: Selectivity radar plot of six sensors tested towards CO, including ethanol, methanol, CH₄, H₂S and NO₂ at optimized temperature of 75 °C, (b) The cross-

selectivity of various sensors towards CO, (c) Response versus CO concentration in the presence of 40% RH, (d-e) repeatability at 20 and 40 ppm CO in the presence of 40 %RH. (f) Real-time resistance plot of showing a long-term stability of a fresh sensor and that tested after three months and (g) response versus CO concentration of a fresh sensor and that tested after three months.

Table 4.1 associates the CO sensing performances of our fabricated SnO₂-NaOH based sensor with the various sensors reported in the literature. Most of the sensors are incorporated with noble metals, which makes sensing fabrication to be very expensive. For instance, Kim et al. [4.14] used Au-SnO₂-co-decorated WS₂ nanosheet based sensor for detection of CO gas at room temperature, showing a response of 3.2. Though an expensive noble metal, such as Pd was loaded on SnO₂ by Mauraya et al. [4.23], nonetheless the sensor still revealed smaller response at elevated temperature of 400 °C. In addition, the review article by Majan et al. [4.33] indicated that the SnO_2 is indeed a workhorse for CO sensing compared to other materials. They have also indicated that to reduce the operating temperature of SnO₂ based sensor, doping with additive, like Pd and Pt or incorporation of other SMO or other materials was considered as a best approach. However, such additives, Pt or Pd are very expensive, which increase the costs of the sensor. Thus, based on Table 1 and the ref. [4.33], our current sensor (i.e., SnO₂-NaOH) indeed showed better sensing capabilities in terms of low operating temperature, lower detection limit. While in terms of an economical point of view, our sensor still demonstrated the lowest fabrication costs.

 Table 4.1: Summary of the CO gas sensing performances of different gas sensor materials.

Materials	Method	CO (ppm)	Temp. (⁰C)	Response	T _{res} (s)	T _{rec} (s)	Refs.
SnO₂-NaOH	Hydrothermal	60	75	22	23	96	This work
SnO ₂	Vacuum evaporation	915	400	77.7%	21	74	13
Au-SnO ₂ -co- decorated WS ₂ nanosheet	Precipitation	50	RT	3.687			[4.14]
MoS ₂ nanosheets- decorated SnO ₂ nanofibers	On-chip electrospinning	100	200	1.5	-	-	[4.15]
Au/MoS2	Chemical vapour deposition	500	60	15%	-	-	[4.16]
CuO/V ₂ O ₅	chemical route	50	300	1.5			[4.17]
Au-V ₂ O ₅	sol-gel method	100	475	40	-	-	[4.18]
TiO ₂ -layer- modified SnO ₂	Atomic layer deposition	1	300	44%*	~5 00		[4.34]
SnO₂ thin film	Spray pyrolysis	260	350	34	28	94	[4.35]
SnO₂ nanowire	Spray pyrolysis	260	350	1	25	28	[4.36]
SnO ₂	Sol-gel method	50	220	55	20	N/A	[4.37]
Ni-SnO2	screen printing	50	375	40	6	39	[4.38]
In/Pd/SnO ₂	Sol-gel	50	140	20	15	20	[4.39]
Pt-SnO ₂	Hydrothermal	100	250	23.18	15	14	[4.40]

Concen., temp. and refs correspond to concentration, temperature and references. *Response = $((R_a/R_g)*100)$.

To further validate the long-term stability of our current sensor towards CO gas, the sensor was stored for 6 months and the effect of storage in the sensor resistance in air (R_a) was investigated, see Fig. 4.7(a). As shown in Fig. 4.7(a), the Ra increased with the storage time, and this increase is more significant for six months storage. As confirmed from the stability analyses, (see the inset, Fig. 4.7(a)), the sensor response decreased after six months of storage, confirming the change in R_a has significant effect on the sensing performance. Such decrease could be due to absorption of moisture during storage.

Furthermore, the SnO₂-NaOH based sensor was tested towards CO at various exposure times, of 5-, 30-, 60- ,180- and 500 min. It was observed that the change in sensor resistance increases with the exposure time. Such behaviour can be witnessed on the sensor response (see Fig. 4.7(c)), which increases with the exposure time. This behaviour clearly shows that the exposure time has a significant effect on the sensing performance. This proposes that our current SnO₂-NaOH based sensor possesses numerous active sites on the surface that need adequate time to be accessed. This demonstrates good signs that these structures possess great ability to be utilized as acetone detection and monitoring even in reduced oxygen environment. This behaviour was also witnessed by Mokoena et al. [4.27], using the p-type NiO nanostructures, which was tested towards propanol vapour.



Fig. 4.7: R_a of the SnO₂-NaOH versus number of months, (b-c) Resistance and response versus exposure time towards 60 ppm CO gas at 75 °C. Note inset corresponds to long-term stability.

4.3.3. Gas sensing mechanism.

The gas sensing mechanism of SnO₂ based sensor as an n-type is based on the change in resistance. Basically, when the sensing layer is exposed in air, the molecular oxygen species gets absorbed on the surface of the sensor. Because of the higher oxygen electron affinity, the oxygen species adsorbed on the surface of the surface of the SnO₂-NaOH sensing layer receive electrons from the SnO₂-NaOH conduction band and gets chemisorbed ions [4.41, 4.42]. Based on the sensing temperature, particular

oxygen species formed (e.g., O_2^- , O^- , and O^{2^-}), result in a creation of a depletion layer to increase the sensing resistance. Lately, the V₀ has been accepted to enhance the sensing performance. The presence of V₀ in an n-type SnO₂-NaOH sensor hastens the adsorption of charge transfer of the CO gas. Basically, individually V₀ provides two electrons, as a result, a higher relative V₀ concentration in the SnO₂-NaOH hollowspheres leads in a greater number of electrons that can be absorbed and utilized for gas sensing performance. In addition, studies have anticipated the new radical Sn⁴⁺- O_2^- that is paramagnetically dynamic and plays a vivacious part in the gas sensing mechanism: as depicted using Kruger Vink notation (Eqs. 4.1-4.3) [4.43].

$$O_O^X \Leftrightarrow V_O^{\bullet} + \frac{1}{2}O_2 + e^-$$
(4.1)

$$O_o^X \Leftrightarrow V_o^{\bullet\bullet} + \frac{1}{2}O_2 + 2e^-$$
(4.2)

$$\operatorname{Sn}^{4+} - \operatorname{O}_{2}^{-} \Leftrightarrow \operatorname{Sn}^{3+} + \operatorname{V}_{0}^{\bullet\bullet} + \operatorname{O}_{2} + 3e \tag{4.3}$$

Thus, upon introducing the CO gas, the adsorbed oxygen ions (0_2^-) interact with the CO molecules and release the trapped electrons back to the conduction band that lessen the depletion layer (see scheme 1), which reduces the sensor resistance. The reaction of the CO molecules on the sensor surface is depicted in eq. 4.4 as:

$$2CO(gas) + O_2^-(ads) \rightarrow 2CO_2(gas) + e^-$$
 (4.4)



Scheme 1: Schematic drawing displaying the mechanism of SnO₂-NaOH towards CO gas.

To elucidate the reason behind improved response of the SnO₂-NaOH based sensor to CO further analyses were performed. According to the XRD analyses, all the SnO₂ based materials displayed the same exposed facets, and crystal structures. Nonetheles, the in-situ analyses from both PL and EPR showed that the SnO₂-NaOH possess more V₀ defects.
EPR studies in Fig. 4.8(a) demostrate that all the SnO₂ and V₂O₅ nanostructures pesent are paramagnetic signal. The paramagnetic signals of the SnO₂-NaOH, SnO₂-NH₄OH, SnO₂-Urea are located at 341.9 mT, 337.1 mT and 340.5 mT, respectively. While the V₂O₅-NaOH, V₂O₅-NH₄OH and V₂O₅-Urea all illustrated the signal at 340.2 mT, showing no shift on the magnetic field. The magnetic field shift observed for the various SnO₂ nanostructures was also witnessed on the XRD results. This was justified as the change in the morphological and structural changes. It is interesting to note that the SnO₂-NaOH shows a broad peak-to-peak (Δ H) signal in comprasion to its counterparts (see Fig. 4.4(a)). This broad signal denotes that the material indeed posseses a singificant amount of defects. It is futher noted that both the SnO₂-NaOH and SnO₂-NH₄OH showed the g-factor of 2.01 associated to the presence of superoxide radical O_{2⁻} that formed due to the electrons transfer trapped in V₀. [4.44, 4.45,]. While the SnO₂-Urea showed a g-factor of 2.2. The V₂O₅ displayed a g-factor of 1.949 associated to characteristic of V^{4+} aggregates [4.46]. As noted in Fig. 4.8(a) and (b), the EPR intensity of the SnO₂-NaOH is larger than that of other SnO₂ structures and as well of those of V₂O₅ nanostructures, denoting higher relative concentration of Vo.

We further carried out the in-situ EPR analyses for SnO₂-NaOH at various temperatures 293K (25 °C), 373K (75 °C) and 448 K (150 °C) to mimic the sensing analyses. As depicted in Fig. 8(c), a slight increase in the paramagnetic signal at 75 °C is observed, while at 150 °C, the signal reduced strongly compared to that at 25 and 75 °C, respectively. The increase in paramagnetic signal is related to a higher relative concentration of V₀. Such increased signal at 75 °C fits well with the superior response witnessed at the same temperature (i.e. 75 °C).



Fig. 4.8: EPR spectra of the various (a) SnO₂ and (b) V₂O₅ nanostructures.

To further support the improved sensing performance induced by SnO₂-NaOH towards CO gas, we conducted the in-situ PL analyses at the same temperatures (23, 75 and 150 °C) used during the gas sensing measurements (see Fig. 4.9). It is interesting that among the nanostructures, only the SnO₂-NaOH displays a strong shoulder in the region of 2.82-3.22 eV and a broad emission of 1.93 - 3.2 eV (Fig. 4.9). This unique emission is consistent with the broad paramagnetic signal observed on the EPR

analyses. Besides, the images in the insets also validate that the base indeed plays a role on the luminescence properties, since the colour changes from black to reddish, then to grey for the SnO₂-NaOH, SnO₂-NH₄OH and SnO₂-urea, respectively. Furthermore, from the supporting information (Fig.A4), the deconvoluted peaks for the SnO₂-NH₄OH and SnO₂-urea samples show peaks at 2.27-3.31 eV, respectively. Basically, typical kind of oxygen defects that behave like luminescence centers in the SnO₂ band gap are Vo, Vo⁺ and Vo⁺⁺. Thus, for the SnO₂, the peak at 3.0 eV is associated to the near band edge (NBE), while the broad emission peak at 2.88-1.92 eV is associated with surface oxygen deficiency state V₀ and electron transition mediated by Vo [4.19]. For the V₂O₅, the emission at 3.1 eV and 2.8 eV are linked to the main transition between the conduction band, Ec (V3d states) and valence band V_B (O2p states) and the band edge transition in V₂O₅ [4.47]. Moreover, the images of the V₂O₅ shows a clear colour change from black to yellow and then to reddish for the V₂O₅ -NaOH, V₂O₅ -NAOH, V₂O₅ -NAOH, V₂O₅ -NAOH, V₂O₅ -NAOH, V₂O₅ -NAOH, N₂O₅ -NaOH, N₂O₅

As noted from Fig. 4.9, the in-situ study denotes that the emission of both SnO_2 and V_2O_5 for all the bases decreases with the operating temperature. It is remarkable to note that while the full width at half-maximum (FWHM) becomes narrower for all other samples with the in-situ temperature, nonetheless, the FWHM of the SnO_2 reflected not to decrease, especially at 75 °C.

The PL emission peak of the temperature in-situ analyses at 75 °C of various bases were compared for both SnO₂ and V₂O₅ (see Fig. 4.9(g) and (h). Among the SnO₂ based samples, the SnO₂-NaOH still revealed a higher intensity and its emisison becoming broad from 1.5 to 3.2 eV. When comapring the SnO₂ and V₂O₅ samples prepared using various bases, it is observed in Fig. 4.6 that the SnO₂-NaOH contains a higher number of defects in comparison to other materials.



Fig. 4.9: PL emission spectra of SnO₂, V_2O_5 nanostructures prepared using various bases measured at different temperatures and comparison of SnO₂ and V_2O_5 nanostructures at 75 °C.

The increase in sensing response is also associated with the smaller crystallite sizes observed for the SnO₂-NaOH, which lead to higher sensitivity and of course increased surface defects, such as V₀. For instance, based on the energy level theory, the particle size of SMO influences the resistances of the materials. Yamazoe et al. [4.48] stated the SnO₂ based sensing sensitivity with particle sizes in the range of 5 and 32 nm. They observed that the sensitivity of SnO₂ based sensor improves strongly once the particle's diameter is smaller than two times the electron depletion layer thickness (L). Besides, Kortidis et al. [4.49] have shown a clear correlation between the crystallite sizes and gas sensing performance, when using ZnO nanostructures prepared at various reaction temperatures. Basically, their sensing response was improved for the smallest crystallite sizes of the material.

Besides, the base may also play a role on the sensing characteristics, since the SnO₂ prepared from NaOH base showed improved response in comparison to other bases (NH₄OH and urea). This could probably be due to the strength of the base, which follows in this manner, i.e., NaOH>NH₄OH>Urea, where the strong base leads to improved formation of porous structures, allowing better gas desorption/adsorption, resulting to superior sensing performance. This demonstrates that the surface enlargement phenomenon is affected by the nature and strength of the base. Sikhwivhilu et al. [4.50] have shown that TiO₂ samples treated with NaOH were more porous and displayed higher surface area in comparison to those treated with other bases (i.e., LiOH or NH₄OH).

To further validate our findings, we linked the sensing performance with the number of spins and the PL intensity ratio extracted from both the in-situ EPR and PL analyses, see Fig. 4.10. Since the V₀ has the capabilities of enhancing the gas detection and sensitivity, as a result the existence of a superior amount of V₀ may be able to enhance

the oxygen adsorption, which in turn improve the interaction between the adsorbed oxygen and the CO gas. Therefore, this justifies the observed increase in CO response with the number of spins (or paramagnetic V₀) and as well as the PL intensity ratio in Fig. 4.10(a) and (b). This behaviour indeed displays a clear correlation. Hence, the quantity of paramagnetic V₀ is linked to the amount of electrons achieving the E_c of SnO₂ [4.43, 4.45]. Motsoeneng et al. [4.46] reported a correlation between the number of spins and propanol response using a SnO₂ hollowspheres based sensor. They also found that the propanol response increases with the paramagnetic V₀. Though their sensing response was roughly 15 at 75 °C. which was twice smaller than the current response (~22). Moreover, Oosthuizen et al. [4.41] reported a clear correlation between the response versus the relative concentration of V₀ and surface to volume ratio.



Fig. 4.10: (a) Response versus number of spins and (b) Response versus PL intensity ratio of SnO₂-NaOH based sensor at various operating temperature. Note that the analyses were done using both in-situ PL and EPR.

Lee et al. [4.51] have reported using the DFT calculation that the presence of V₀ does not only enhance the electron concentration in E_c of the sensing layer. It further persuades a creation of the local built-in electric field, enhancing the electron migration proportion in the sensing layer. Additionally, the electron transfer movement after interaction with the adsorbed oxygen, is better in comparison to that after interaction with CO gas. The presence of V₀ is beneficial to endorsing the creation of numerous adsorbed $O_{2^{-}}$ on the sensing layer surface, establishing an extensive electron depletion layer. Consequently, existence of V₀ plays a significant character in enlightening the CO gas response of the SnO₂-NaOH based sensor.

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Room temperature gas sensing of SnO₂/CuO heterostructures for the detection of NO₂ gas: Low-power Consumption gas sensor

5.1. Introduction

The demands of gas sensors have increased over the years as a means of minimizing the risk of air pollution and identifying dangerous, flammable, and poisonous gases that might endanger human heaths and the environment. Among other gases NO₂ is the most toxic gas. In South Africa, the populations are endangered from the sources that release NO₂ during operation, such as car exhaust, household and mining industries [5.1, 5.2]. Gas sensors are useful in coal industries to monitor the leakage of NO₂ from the containers and machines during manufacturing, which may lead to harm or explosion. Whereas in some houses where they used gas, wood, oil, kerosene, cigarettes and coal burning appliance, such as stoves, heaters, furnaces, boilers and fireplaces and gas engines, in cars and home generators, which contribute to the elevation of NO₂ levels makes gas sensor devices more preferable [5.3-5.6]. Semiconductors metal oxide (SMOs) gas sensors, among other gas sensors mentioned in the literature, have gained researchers' attention because of their chemical and physical characteristics [5.7]. Large sensitivity, low operating temperature (RT), stability, selectivity, and high surface area are some challenges that have been encountered in gas sensing [5.8]. To meet this requirement, researchers have introduced doping and annealing processes for materials [5.9]. Gas sensors are

needed that have fast reaction times, high sensitivity, fast recovery times, low working temperatures, and strong selectivity for a variety of gases.

Copper oxide CuO, a p-type semiconductor metal oxide with a band gap of 1.7 eV, finds extensive use in gas sensors [5.10]. Due to its potential use in gas sensors, solar cells, lithium-ion batteries, and light emission, among other things, Tin dioxide (SnO₂) which is an n-type semiconductor metal oxide with a wide band gap of 3.6 eV, has attracted interest in several research areas. This is because of its chemical and physical characteristics, which include low cost, low resistance, high transparency, and high electrical conductivity [5.11]. To improve the materials' detecting capabilities, SnO₂/CuO composite has been synthesized for use in gas sensors using facile hydrothermal procedures.

5.2. Experimental method

5.2.1. Material used

Tin chloride dehydrate (SnCl₂.2H₂O) and Copper (II) acetate monohydrate (C₄H₈CuO₅).

5.2.2. Synthesis

The autoclave hydrothermal method was employed to synthesis pure SnO₂, CuO and SnO₂/CuO with various molar concentrations (0.5:1.0M, 1.0:0.5M and 1.0:1.0). The certain amount of SnCl₂.2H₂O and (C₄H₈CuO₅), 0.5M of SnCl₂.2H₂O and 1.0M of C₄H₈CuO₅ precursors were added in separate beakers with 150ml of distilled water, the solution was stirred for 1 hour using magnetic stirrer. The solution was then deposited in a Teflon liner then into autoclave stainless steel before heated at 180°C

in an oven for 16 hours. The solution was then cooled and the products was centrifuged 10 times in the time interval of 10 minutes using mode-TJ-6 centrifuge machine. The product was heated (dried) at 90°C, the final product SnO_2 and CuO power were then grinned using pestle and mortar. The power were then characterized. The same procedure was repeated for SnO_2/CuO with the mole ratio of (1.0:0.5M and 1.0:1.0).

5.2.3. Characterization

The structure of the materials was probed using a (XRD, Bruker AXS D8 Advance xray diffractometer, Cu K α radiation λ = 0.154056). The scanning electron microscopy (SEM, ZEISS Auriga) and transmission electron microscopy (Tecnai) were utilized to examine the surface morphology, internal structure and elemental composition of the materials. UV-vis spectrometer was used to study the optical characteristics of the the materials.

5.3. Results and discussion.

Fig. 5.1 displays the XRD patterns of SnO₂/CuO with various molarity (0.5: 1.0M, 1.0: 1.0M and 1.0: 0.5) and of pure CuO and SnO₂ respectively. The SnO₂/CuO, CuO and SnO₂ samples were annealed at 400 °C for two hours. The XRD pattern for pure SnO₂ depict all peaks in an amorphous nature implying the disorderly arrangement within each diffracting angles. All peaks for pure CuO shifted with approximately 1° to lower diffracting angles, which may be attributed to crystallite sizes and lattice strain. Moreover, sharper peaks are observed indicating that CuO has higher crystallinity with low intensities which may be due to chaotic arrangement (disorder) of crystal at all the diffracting angles. The present of unknown peak is observed at 20=25.46° which is

due to impurities. The CuO XRD pattern depicts a monoclinic structure despite the shifts, forming a single CuO phase.

The XRD pattern of SnO₂/CuO-0.5:1.0M depicts peaks at 20=26.75°, 20=33.86°, 20=35.66 °, 20=38.84 °, 20=49.90 °, 20=51.12 °, 20=58.40 ° and 20=61.67 ° which correspond to the following planes of SnO₂ (110), (101), (200), (210), (211), (220), (022) and (310) which confirm that SnO₂ has a tetragonal structure which agree with the standard (JCPDS card no. 01-077-0452). The broad peaks observed at 2θ=26.75°, 20=33.86 ° and 20=51.12 ° exhibited that the material has poor crystallinity for those diffracting peaks which may be due to the synthesis method applied. The XRD pattern of SnO₂/CuO-1.0:1.0M reveals peaks at 20=26.81°, 20=33.95°, 20=35.68°, 20=38.86 °, 20=49.00°, 20=52.00°, 20=58.38° and 20=61.80° corresponding to the following planes of SnO₂ (110), (101), (200), (210), (211), (220), (022) and (310), the present of sharper peaks are observed indicating good crystallinity and broad peaks indicating poor crystallinity at other diffracting angles are also observed. The XRD pattern for SnO₂/CuO-1.0:0.5M and SnO₂/CuO 1.0:1.0M depict similar peaks but with different unequal intensities. The materials formed only one phase and there are no unknown peaks revealing that the materials are pure. The molar concentrations have impacts on the crystallinities of the materials, this is supported by various XRD pattern as some peaks are amorphous and some has improved crystallinity. The crystallite sizes (D) of the materials listed in Table 5.1 were calculated using Debye's Scherrer equation:

$$\mathsf{D} = \frac{\kappa\lambda}{\beta\cos\left(\theta\right)} \tag{5.1}$$

where D is the particle size, K is known as the Scherer's constant (K=0.9), λ is the X-ray wavelength (1.5406Å), β (in radians) is full width at half maximum (FWHM) of the

diffraction peak and θ is the diffracting angle between planes. The space (d) between the crystal layer is calculated using equation (5.2)

$$d = \frac{n\lambda}{2sin(\theta)}$$
(5.2)

where λ is the wavelength of the x-ray, *d* is the spacing of the crystal layer and θ is the incident angle.



Fig. 5.1: XRD pattern of pure SnO₂ and CuO, SnO₂/CuO with different molar concentration and SnO₂, CuO standard JCPDS.

Table 5.1. Calculated values for FWHM using Origin and Crystallite size using Scherrer equations and Lattice parameters for the synthesized SnO₂, CuO, SnO₂/CuO with different molar concentrations.

Material	FWHM	d-spacing	Crystallite size by	Position	planes
	β (rad)	(nm)	Debye's formula (nm)	(°)	
SnO ₂	0.036	0.14	3.95	26,34	(110)
CuO	0.040	0.12	3.46	24.82	(110)
SnO ₂ /CuO- 1.0:0.5M	0.010	0.08	14.01	38.86	(111)
SnO ₂ /CuO- 1.0:1.0M	0.040		3.58	26.78	(110)
SnO ₂ /CuO- 0.5:1.0M	0.006	0.12	24.09	38.86	(111)

Fig. 5.2 shows the SEM micrographs of the SnO₂/CuO heterostructures. The SnO₂/CuO- (1.0:0.5M) in Fig. 5.2(a) shows agglomerated nanoparticles. While the SnO₂/CuO- (1.0:1.0M) in Fig. 5.2(b) displays spherical nanoparticles with an average diameter of 50 nm. The surface morphology shows a porous structure, which could be suitable for adsorption gas molecules. The SnO₂/CuO- (0.5:1.0M) in Fig. 5.2(c) shows larger nanoparticles, with an average diameter of 70-100 nm.



Fig. 5.2. SEM micrographs of (a) SnO₂/CuO-(1.0:0.5M), (b) SnO₂/CuO- (1.0:1.0M) and (c) SnO₂/CuO- (0.5:1.0M).

High resolution-TEM micrographs of the SnO₂/CuO heterostructures of various molar concentration are shown in Fig. 5.3 (a), (c) and (e). As shown in Fig. 5. all the nanostructures are made of nanoparticles, and this confirm the SEM findings. The selected area electron diffraction (SAED) patterns in Fig. 5.3 (b), (d) and (f) shows that the materials are polycrystalline. The SAED in Fig. 5.3 (b) and (d) shows diffused Debye ring, indicating that the materials are amorphous as confirmed from the XRD analyses. The SAED in Fig. 5.3 (f) shows that the materials are more crystalline than

its counterparts. Additonally, several planes associated with CuO and SnO₂ were observed.



Fig. 5.3: HR-TEM images (a) SnO_2 -CuO (1: 0.5), (c) SnO_2 -CuO (0.5: 1), (e) SnO_2 -CuO (1:1), corresponding to SAED patterns (b), (d) and (f)

To confirm an appropriate distribution of CuO on SnO₂ matrix, STEM- EDS SI maps of CuO/SnO₂ -(1.0:1.0M) were carried out. From the maps in Fig. 5.4, it is evident that both Cu, Sn and O are distribubeted homogeneuosly.



Fig. 5.4: STEM-EDS maps of CuO/SnO₂ -(1.0:1.0M).

Fig. 5.5 shows UV-vis absorption spectra of pure and the plots $(F(R) hv)^2$ against (hv) for SnO₂, CuO, SnO₂/CuO-(1.0:1.0M), SnO₂/CuO-(1.0:0.5M), SnO₂/CuO-(0.5:1.0M). The measurements were taken from 800 to 300 nm. The energy band gap were extracted by Kubelka-Munk equation (KM) were absorption $(F(R) hv)^2$ equal to zero, using dash line as indicated in the fig. 5.5 (f), the band gap energy were found to be 3.26eV for SnO₂, which is close to the reported band gap [5.11], 1.58eV for CuO, which is near the reported band gap of 1.4 eV [10], 2.97eV SnO₂/CuO-(1.0:1.0M), 3.30eV for SnO₂/CuO-(1.0:0.5M) and 2.32eV for SnO₂/CuO-(0.5:1.0M) respectively. The band gap energy increases due to the reduction of the crystal size.



Fig. 5.5: UV-vis absorption spectra of pure (a) SnO_2 , (b) CuO, (c) $SnO_2/CuO-1.0:1.0$ M,(d) $SnO_2/CuO-1.0:0.5$ M and (e) $SnO_2/CuO-0.5:1.0$ M. (f) The Kubelka-Munk (K-M) plots (F(R) hv)² against (hv) for pure SnO_2 and CuO, and their heterostructure with different molar concentration ratio.

Fig. 5.6 (a) presents the resistance-time plots for SnO₂/CuO-(1.0:1.0 M), SnO₂/CuO-(1.0:0.5 M SnO₂/CuO-(0.5:1.0 M) heterostructures tested toward NO₂ at room temperature and 100 °C. The change in electrical signals is observed when the sensors are exposed to NO₂ gas at that operating temperature. The sudden increase is resistances of the sensors is observed when exposed to oxidising gas of NO₂, this shows that the composites exhibit n-type conductivity behaviours. The sensors exhibited the response when the gas was injected in the test chamber and recovered incompletely when the gas was flushed out with air, which may be due to the NO₂ gas remained in the test chamber. The different molar concentrations have effect on the

sensing behaviour of the nanocomposites. This indicates that the sensors could only respond at room temperature, which is considered as an optimal temperature.



Fig. 5.6: The plots of (a) Resistance against time, and (b) Response against concentration for SnO₂/CuO-(1.0:1.0 M) and SnO₂/CuO-(0.5:1.0 M) at 25 °C, for NO₂ gas.

Fig. 5.7(a) shows the response of the sensors when exposed to different NO₂ concentrations at room temperature. At 10 ppm, the SnO₂/CuO-(1.0:1.0 M) and SnO₂/CuO-(0.5:1.0 M) had a response of 1.05 and 1.04, respectively. While higher concentration (100 ppm), the SnO₂/CuO-(1.0:1.0 M), disclosed the highest response of 1.13. The higher response could be justified by smaller nanoparticles observed from the SEM analyses, leading to reduced crystallite sizes.

Fig. 5.7(b) shows the radar selectivity plot of various sensors towards different gases. The SnO₂/CuO-(1.0:1.0 M) shows better selectivity, followed by SnO₂/CuO-(0.5:1.0 M)-based sensor towards NO₂ gas in comparison to other gases. This shows that the sensors could some-how be useful for detection of NO₂.



Fig. 5.7: Response versus NO₂ concentration, and (b) radar selectivity plot.

Table 5.2 shows the comparison behavior of the various sensors from the literature with the current work. Compared to sensors prepared in refs. [5.14] and [5.15], our sensor shows better response/recovery times. Moreover, with respect to ref. [5.15], our sensor further shows improved response. Though we should point out that further improvement in synthesis approach is required, by either doping with noble metals to improve the sensitivity of our sensors. Such work will be considered in the future.

Materials	Technique	NO ₂	Temperature	Response	Tres/Trec	Refs
		(ppm)	(°C)		(s)	
SnO ₂ /CuO-	Hydrothermal	10	25	1.13	50/77	This
(1.0:1.0 M)						work
CuO	Hydrothermal	5	25	1221.3	6.8/55.1	[5.12]
CuO	Hydrothermal	40	75	39.0	-/-	[5.13]
SnO ₂	Hydrothermal	10	25	94	10/413	[5.14]
V ₂ O ₅	Sputter	100	150	32.5%	102.29	[5.15]
	deposition				/778.23	
rGO-Co ₃ O ₄	Hydrothermal	60	25	80	120/	[5.16]

 Table 5.2: Summary of the NO2 gas sensing performances of different gas sensor

 materials.

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CHAPTER 6.

SUMMARY

Various SnO₂ and V₂O₅ nanostructures were efficiently synthesized using a hydrothermal method in different base solutions. Surface analyses illustrated that the SnO₂-NaOH possessed hollowspheres like structures with a chirped/etched surface, while the SnO₂-NH₄OH and SnO₂-Urea showed nanoflakes and hierarchical spheres with smooth edges, respectively. The V₂O₅-NaOH showed nanorod like structures, which are attached to one another, while the V₂O₅-Urea displayed hexagonally shaped thick rods like structures. XRD analyses displayed that both the SnO₂ and V₂O₅ were highly crystalline and the SnO₂ followed the following behaviour in terms of crystallinity: SnO₂-NH₄OH>SnO₂-Urea>SnO₂-NaOH. The nanostructures were further analysed using In-situ EPR and in-situ PL studies. Both the in-situ PL and EPR showed that the SnO₂-NaOH contained a higher number of V₀. Sensing performances of the designed gas sensors were evaluated toward CO in the presence of other interference gases, H₂S, CH₄, NO₂ and VOCs, such as methanol and ethanol. The SnO₂-NaOH based sensor demonstrated improved response and selectivity towards CO gas at 75 °C from the tested six sensors. Additionally, the SnO₂-NaOH based sensor illustrated the lowest theoretical detection limit of 70 ppb. These findings point out that the SnO₂-NaOH based sensor is a favourable, reliable, and economical solution for detection of CO gas for the air quality monitoring at ppb-level. This versatile tunability on SnO₂ hollowspheres derived from the use of NaOH base introduced a new avenue for fabricating distinct and tailored sensors for detection of CO at a low operating temperature. Thus, the future work will focus on improving the stability, while maintaining the sensitivity.

Moreover, with respect to low temperature detection of NO₂, the SnO₂/CuO-(1.0:1.0 M), SnO₂/CuO-(0.5:1.0 M) and SnO₂/CuO-(1.0:0.5 M) heterostructures-based sensors were fabricated. Various instrumentations validated the formation of heterostructures. Among the tested sensors, the SnO₂/CuO-(1.0:1.0 M)-based sensor demonstrated higher response towards NO₂, in the presence of other four gases at room temperature. At higher temperature of 100 °C, the sensors showed poor response, justifying that their optimal temperature is 25 °C. These findings point out that these sensors could be considered as low-power consumption sensors for detection of NO₂.

Future Work:

- Focuses on further improving the approach of synthesis method.
- Investigate the long-term stability in dry air and in the presence of relative humidity (i.e., 0-60 %)
- Improve the sensitivity by introducing noble metals (i.e., Au, Pt, Ag) on the surface of SnO₂/CuO.
- Investigate the effect of bias voltage on the sensing performance.
- Investigate the low concentration of NO₂ (<5 ppm).
- Attempt to fabricate self-powered sensors for the purpose of low-power consumption.

Low Temperature Tunability on CO Selectivity, Low Detection Limit Based on SnO₂-Hollowspheres Induced by Various Bases



Fig. A1: EDS spectra of SnO₂-NaOH, SnO₂-NH₄OH and SnO₂-Urea



Fig. A2: Response versus CO concentration at (a) 25 and (b) 150 °C.



Fig. A3: Response and recovery times of various nanostructures towards CO at 75 °C.



Fig. A4: PL fitted plots of SnO_2 -NaOH, SnO_2 and SnO_2 -Urea measured at different Temperatures.